

Boulder Summer School 2005 – Lectures 2 & 3

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Electron Dephasing and Energy Exchange in Diffusive Metal Wires:

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With special thanks to Hugues Pothier!

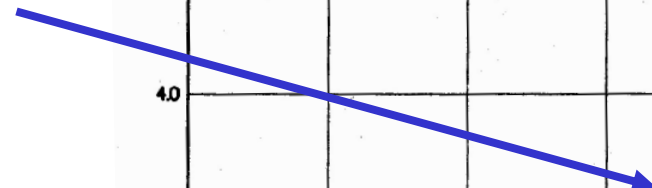
Work supported by NSF DMR

Prologue

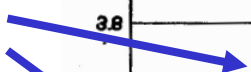
Resistivity of metals

Pt

High T, phonons



Low T, impurities & disorder



$dR/dT > 0$ always

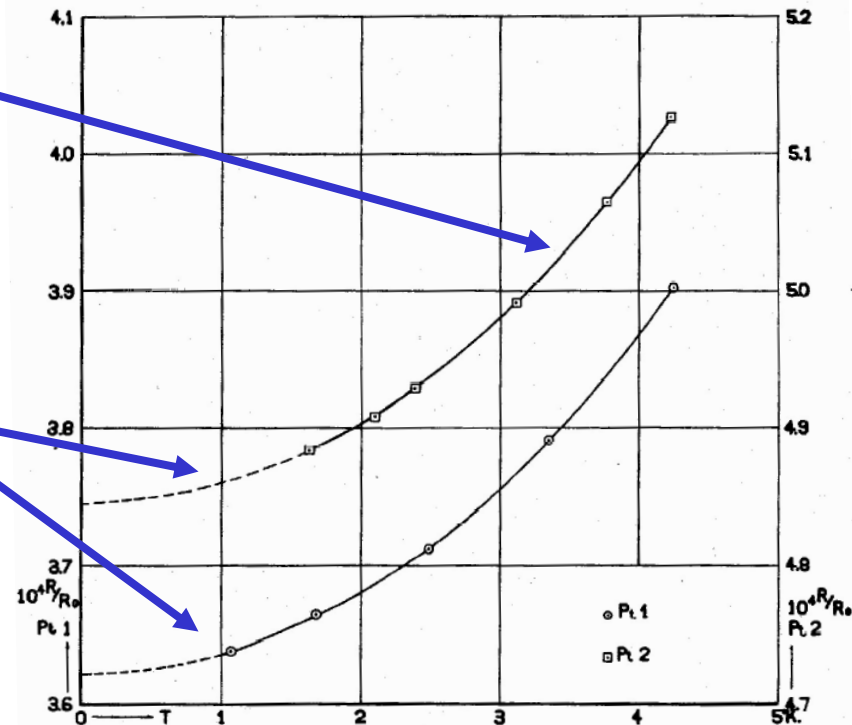


Fig. 1. Electrical resistance of Pt between 0°K. and 4.2°K.

De Haas & de Boer, 1934

But $dR/dT < 0$ in some samples!

Au

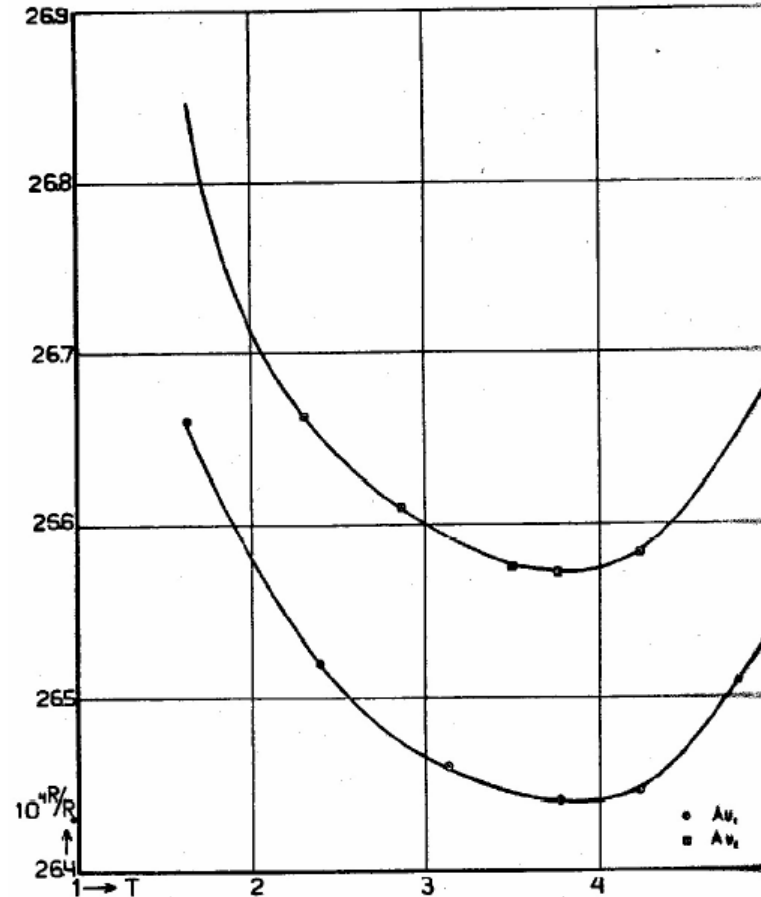


Fig. 1. Resistance of Au between 1°K. and 5°K.

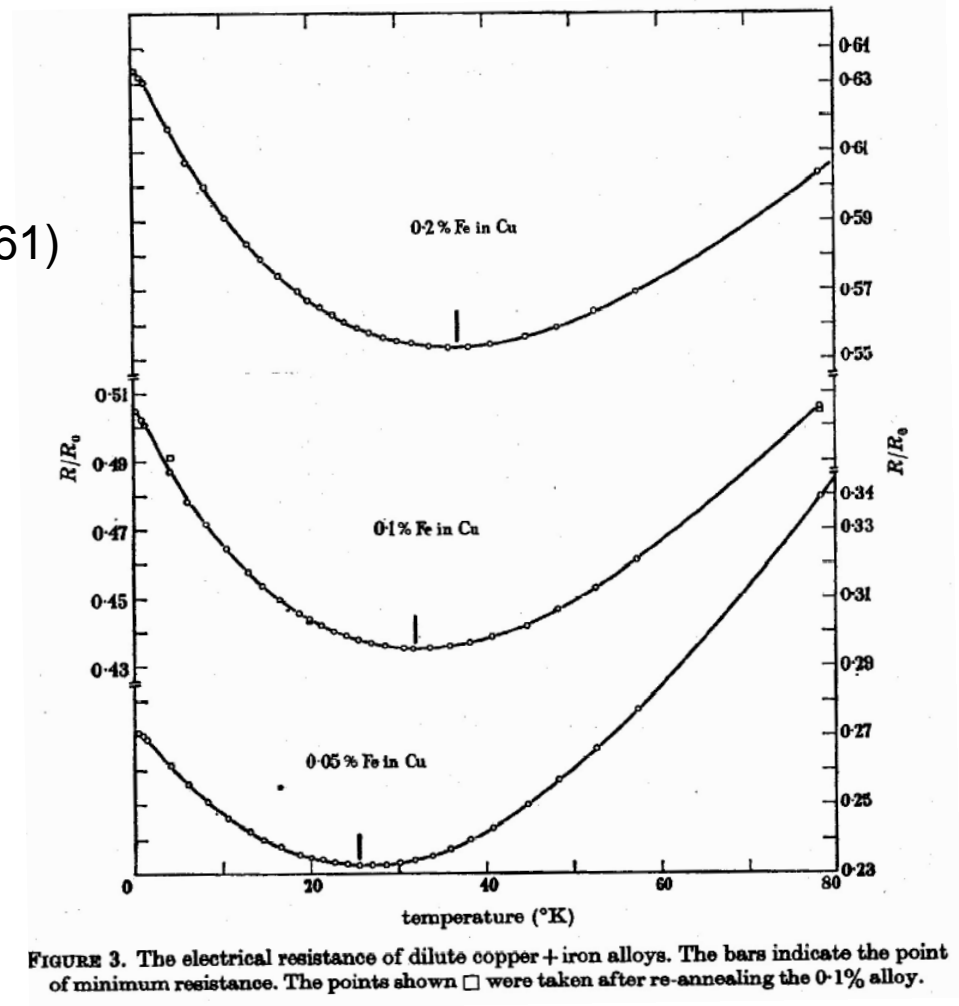
De Haas, de Boer, & van den Berg, 1934

Suspect magnetic impurities

Fe in Cu:

J.P. Franck, Manchester, Martin (1961)

But how do they work?



The solution

Progress of Theoretical Physics, Vol. 32, No. 1, July 1964

Resistance Minimum in Dilute Magnetic Alloys

Jun KONDO

The s-d exchange model: $H = \sum_i J \vec{s}_i \cdot \vec{S}$

Kondo's result: $\delta\rho \propto -B \log\left(\frac{T}{T_K}\right) \Rightarrow \frac{d\rho}{dT} < 0 \quad !!$

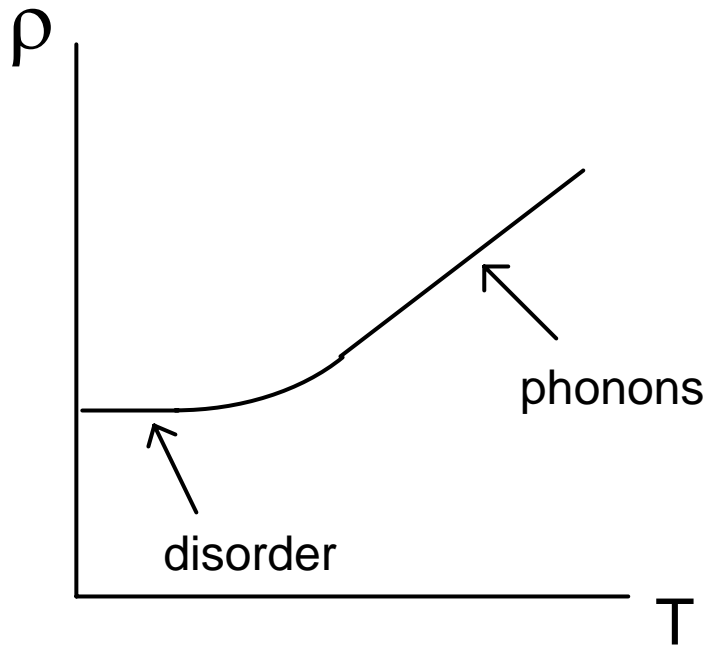
Kondo temperature: $k_B T_K \approx E_F e^{-\frac{1}{vJ}}$

v = density of states at E_F

1960's

Moral of the story: magnetic impurities dominate the low-temperature resistivity of metals, even at concentrations as low as 0.01%

Jump ahead 20 years ... 1980's



WRONG!

$$\rho = \frac{m}{ne^2} \frac{1}{\tau}$$

Matthiessen's rule:

$$\frac{1}{\tau} = \frac{1}{\tau_{disorder}} + \frac{1}{\tau_{el-ph}} + \dots$$

elastic

inelastic

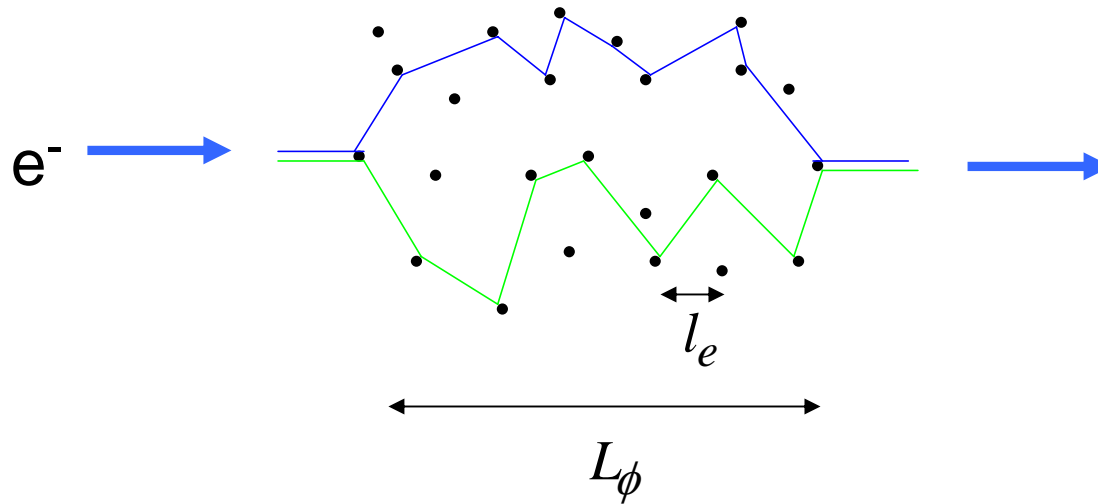
preserves quantum phase coherence

destroys quantum phase coherence

Low T: $\frac{1}{\tau_{inelastic}} \ll \frac{1}{\tau_{elastic}}$

Electrons maintain quantum phase coherence over distance $L_\phi \gg l_e$

Electron transport in diffusive regime



1. Elastic scattering (film boundaries, impurities) $l_e = v_F \tau_e$

→ diffusive states $D = \frac{1}{3} v_F l_e$

2. Inelastic scattering (phonons, other electrons, spins)

→ loss of phase coherence $L_\phi = \sqrt{D \tau_\phi}$

→ energy exchange between electrons

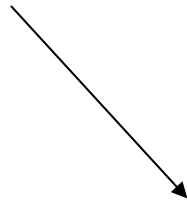
Why Is the Phase Coherence Time Important?

- τ_ϕ limits quantum transport phenomena:
 - normal metals: weak localization, UCF, Aharonov-Bohm
 - superconductors: proximity & Josephson effects
- Localization theory assumes $L_\phi > \xi$
 - no M-I transition if τ_ϕ saturates at low temperature
- example of quantum system coupled to environment

Predictions for τ_ϕ at low T

(Altshuler & Aronov, 1979)

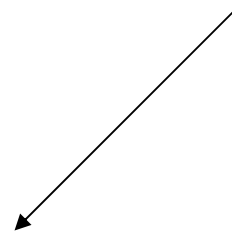
At low T, τ_ϕ limited by
e-e interactions



τ_ϕ depends on
dimensionality

Screening depends on
dimensionality

(At energy E,
compare $\sqrt{\hbar D/E}$ with
transverse dimensions)



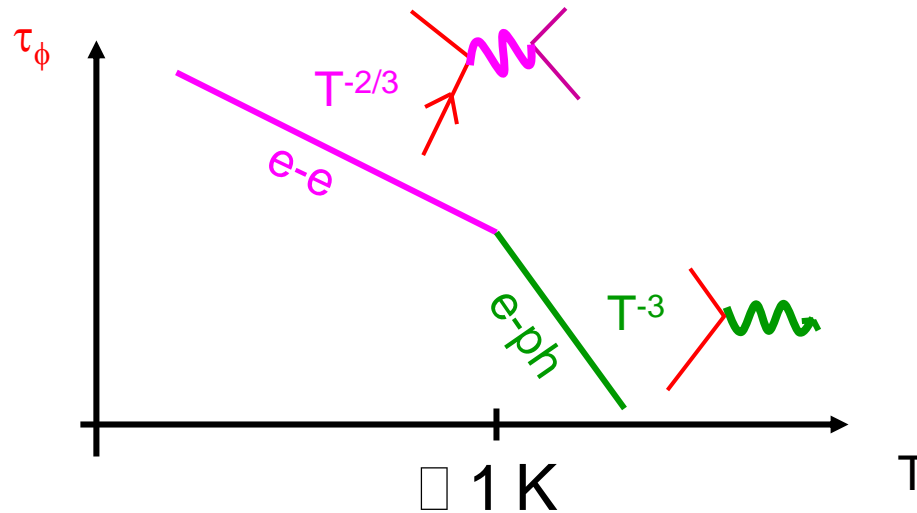
$$\left(\sum_{q_x, q_y, q_z} \frac{\dots}{(Dq^2 + i\omega)^{\dots}} \right)$$

« wires » (1d regime) : $L_\phi = \sqrt{D\tau_\phi} >$ transverse dimensions

($E \sim \hbar/\tau_\phi$ rule the game)

$\tau_\phi(T)$ in wires

(Altshuler, Aronov, Khmelnitskii, 1982)



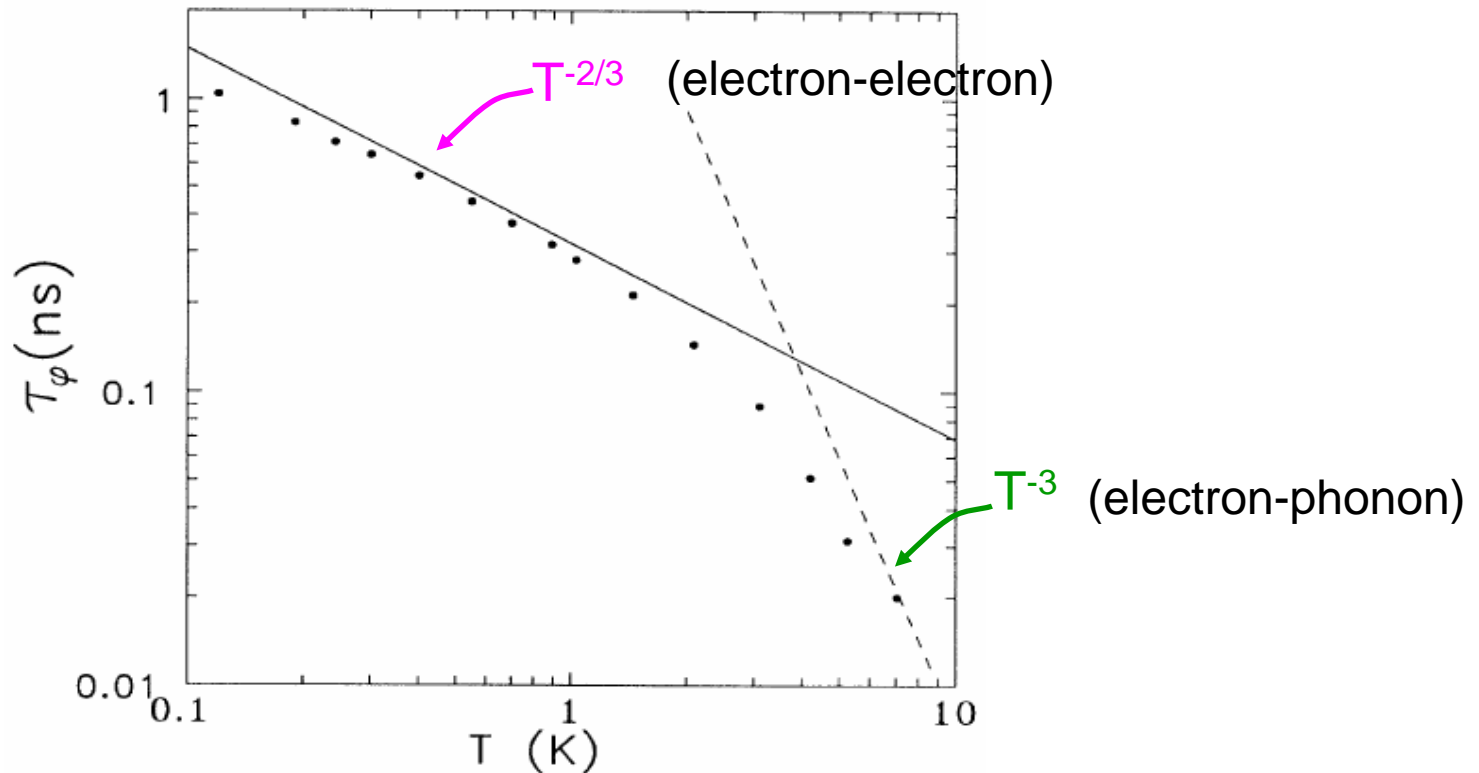
$$\tau_\phi = (A T^{2/3} + B T^3)^{-1}$$

$$A = \frac{1}{\hbar} \left(\frac{\pi k_B^2}{4v_F L w t} \frac{R}{R_K} \right)^{1/3}$$

Screened Coulomb interaction at $d=1$

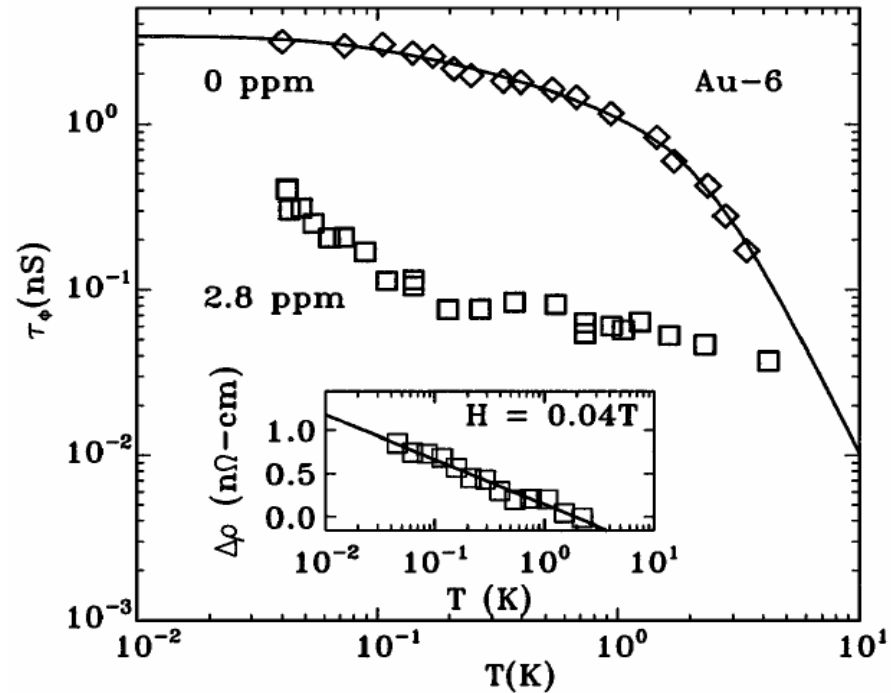
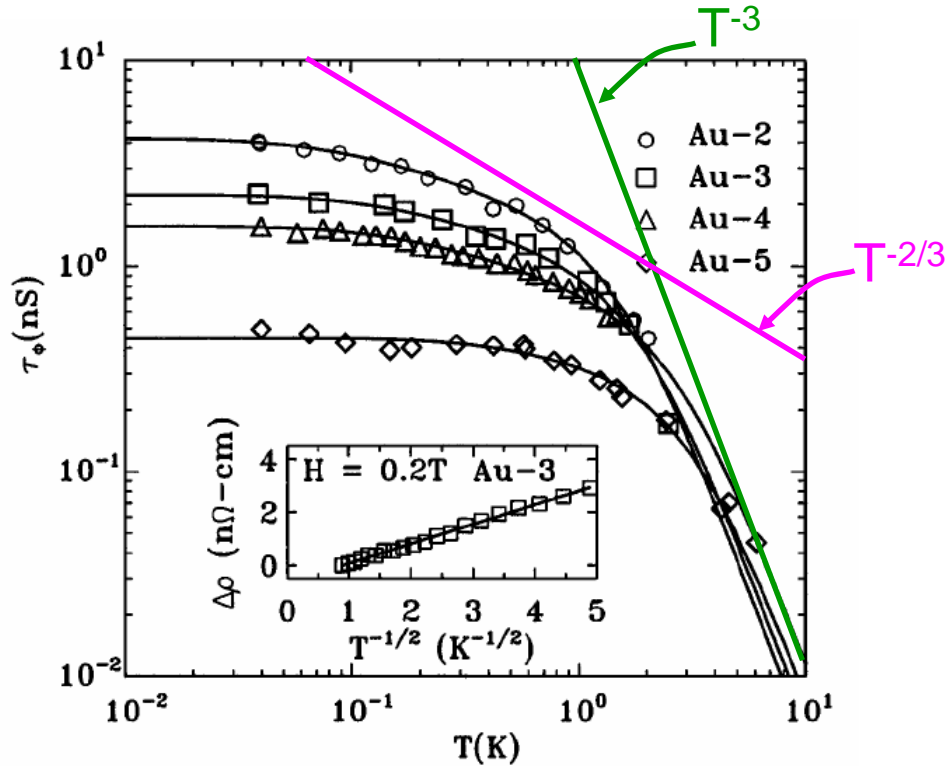
Temperature dependence of τ_ϕ confirmation of AAK theory in quasi-1D

Echternach, Gershenson, Bozler, Bogdanov & Nilsson, PRB **48**, 11516 (1993)



The Experimental Controversy

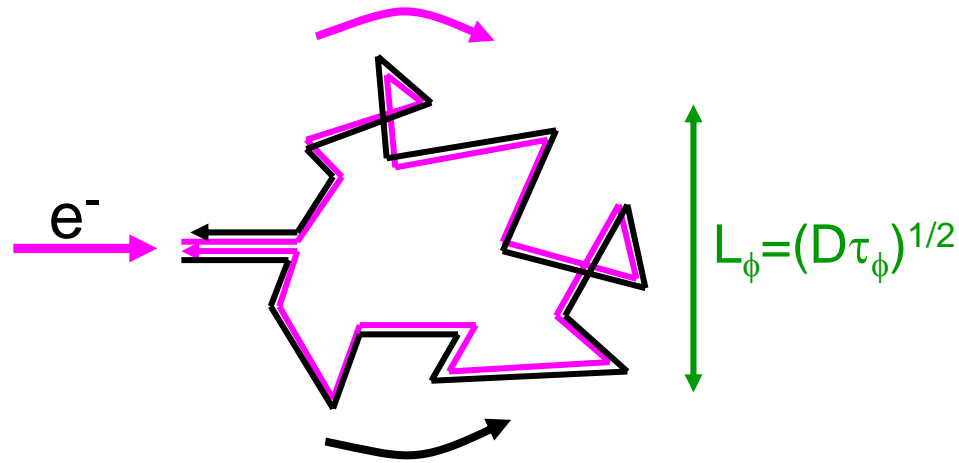
Mohanty, Jariwala and Webb, PRL **78**, 3366 (1997)



Saturation of τ_ϕ :

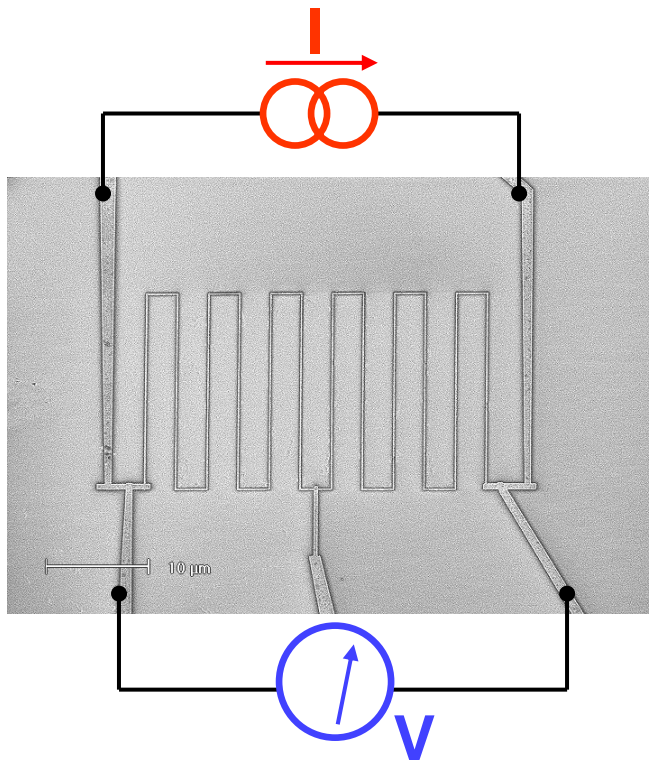
**Artifact of measurement ?
If not, is it intrinsic ?**

Measuring $\tau_\phi(T)$

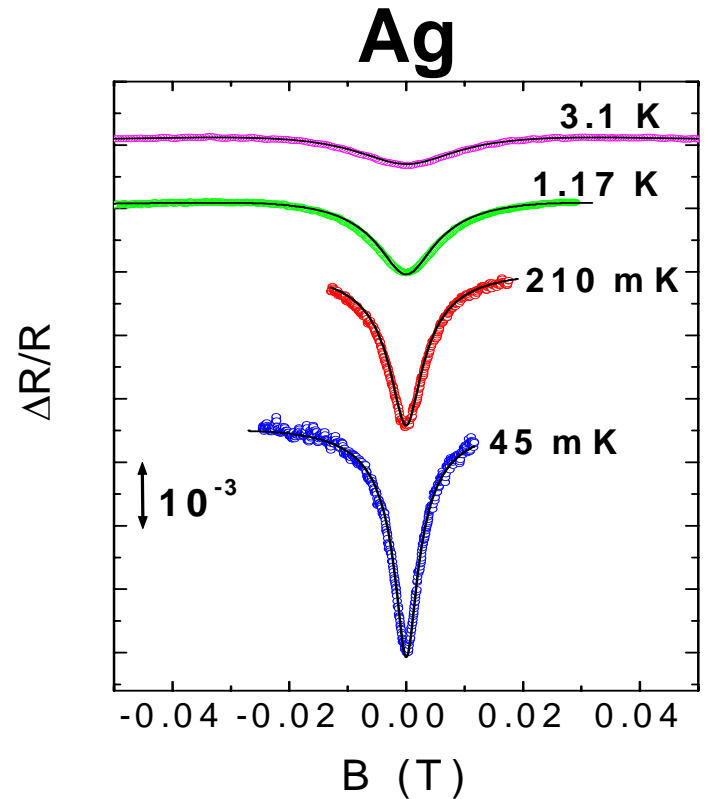


Interference of time-reversed paths
 \Rightarrow “weak-localization” correction to R

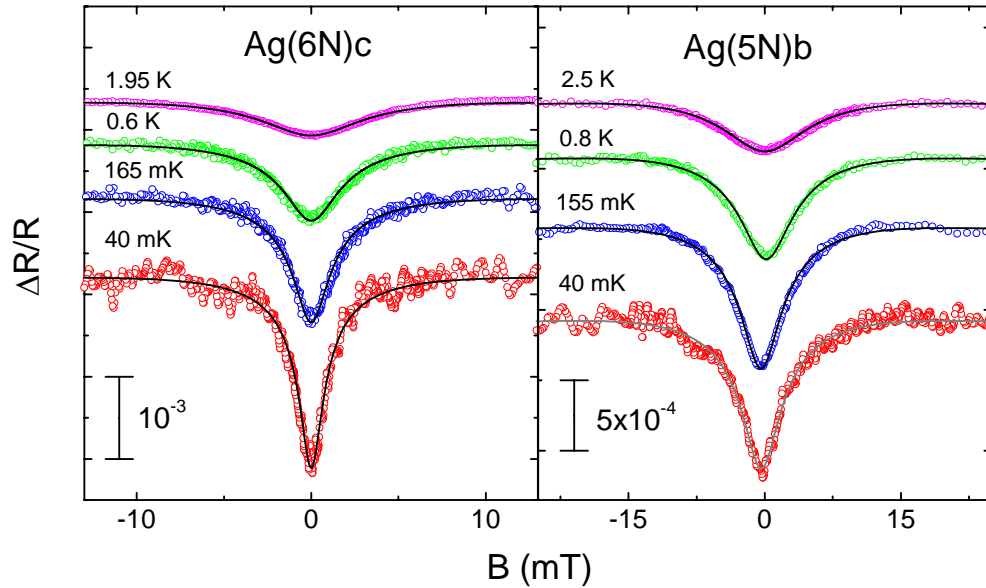
B reduces weak-loc. correction



\odot **B**
 $L \sim 0.25$ mm



Measuring $\tau_\phi(T)$: raw data



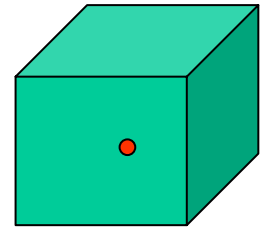
5N = 99.999 % source purity

6N = 99.9999 % “ “

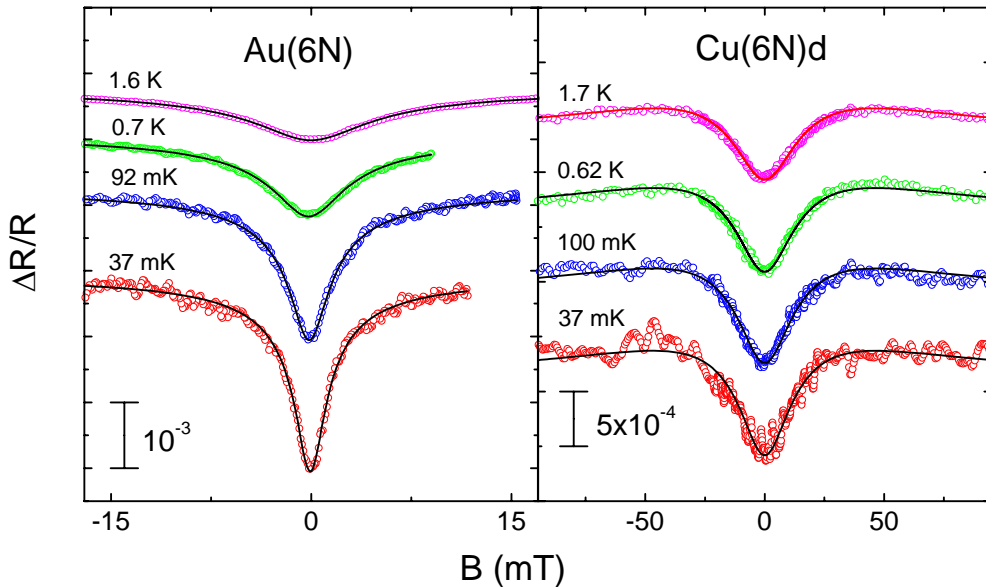


1 ppm of

impurities :



100 atoms ~ 25 nm



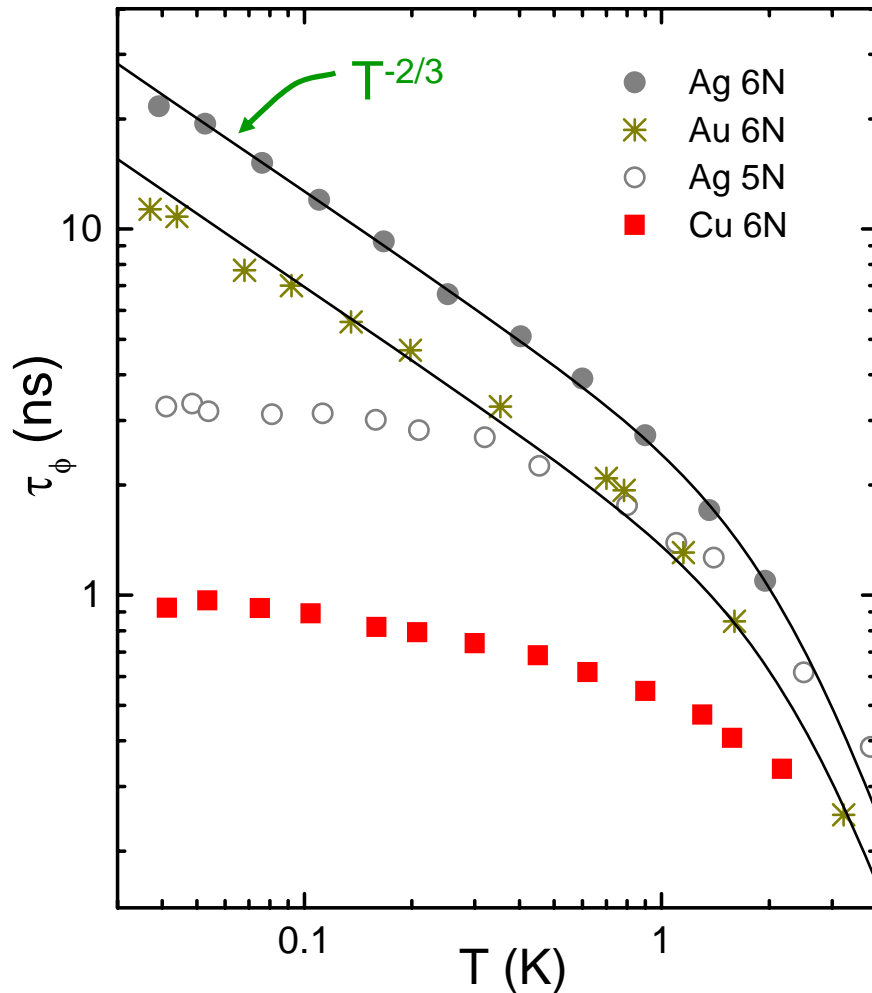
Ag(6N) & Au(6N):

ΔR grows as T decreases

Ag(5N) & Cu(6N):

ΔR saturates below ~ 100mK

$\tau_\phi(T)$ in Ag, Au & Cu wires



5N = 99.999 % source material purity
6N = 99.9999 % “ “ “

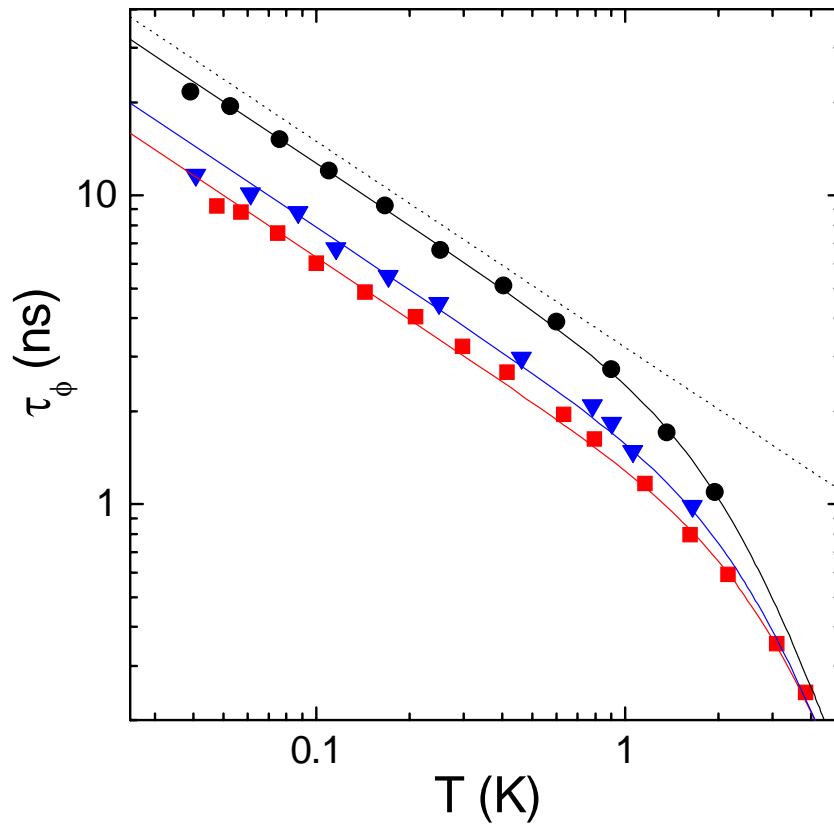
Low T behavior vs. Purity:

- Ag 6N, Au 6N
→ agreement with AAK theory
- Ag 5N, Cu 6N
→ saturation of $\tau_\phi(T)$

Saturation of τ_ϕ is sample dependent

Quantitative comparison with AAK theory for clean samples

$$\tau_\phi = (A T^{2/3} + B T^3)^{-1}$$



Sample	A_{thy} ($\text{ns}^{-1} \text{K}^{-2/3}$)	A ($\text{ns}^{-1} \text{K}^{-2/3}$)
■ Ag(6N)a	0.55	0.73
▼ Ag(6N)b	0.51	0.59
● Ag(6N)c	0.31	0.37
● Ag(6N)d	0.47	0.56
● Au(6N)	0.40	0.67

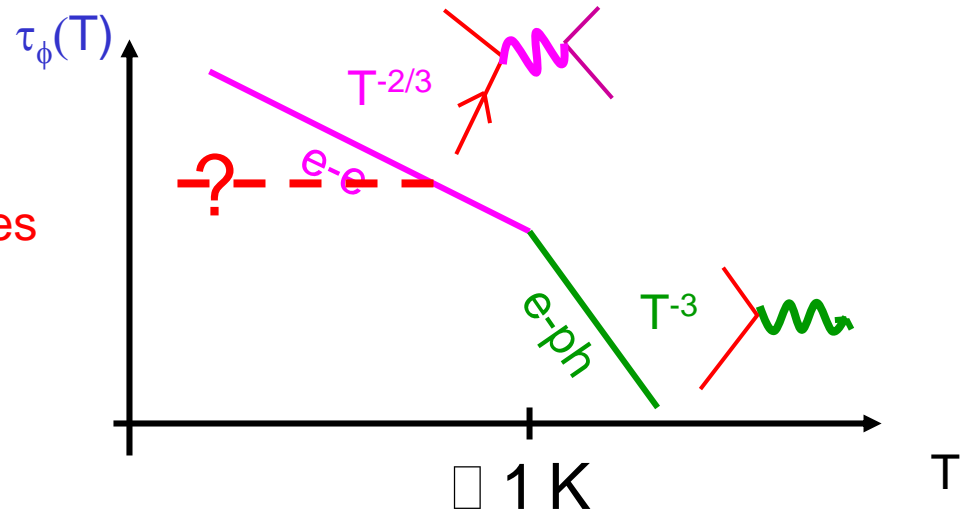
F. Pierre *et al.*,
PRB **68**, 0854213 (2003)

$$A_{thy} = \frac{1}{\hbar} \left(\frac{\pi k_B^2}{4v_F L w t} \frac{R}{R_K} \right)^{1/3}$$

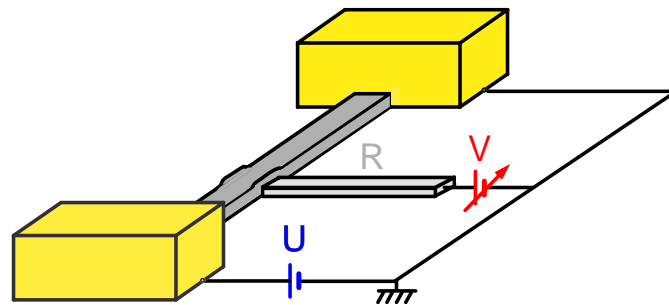
Investigation of inelastic processes

1st method : τ_ϕ

Another process dominates
in not-so-pure samples?



2nd method : measure energy exchange rates



Distribution $f(E)$
reflects the
exchange rates

Background: Shot noise in diffusive metal wires

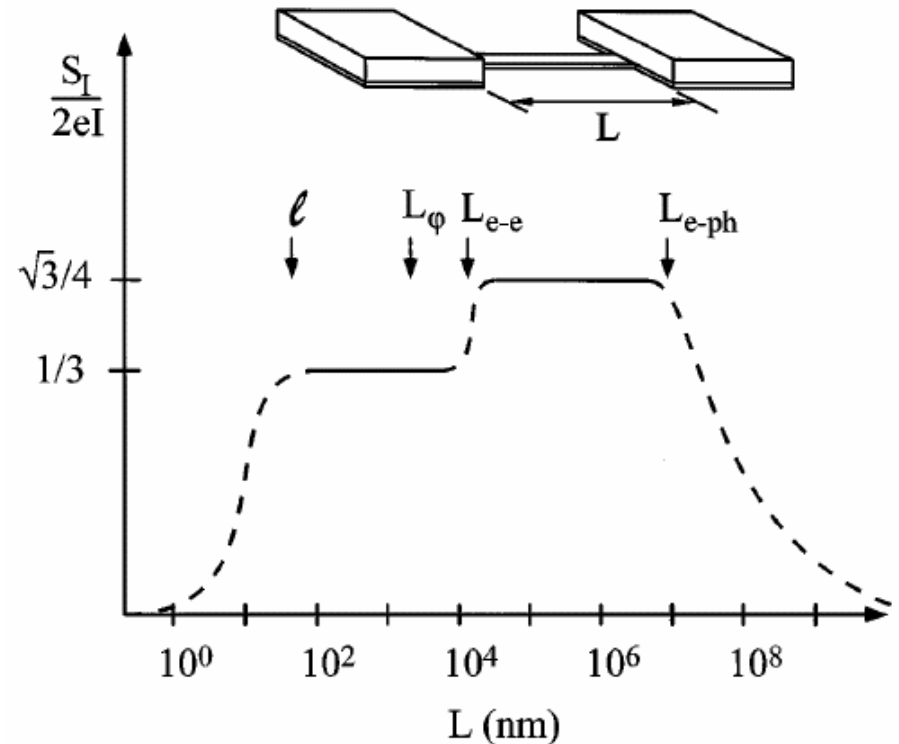
Steinbach, Martinis and Devoret, PRL **76**, 3806 (1996)

Theory:

Nagaev 1992, 1995

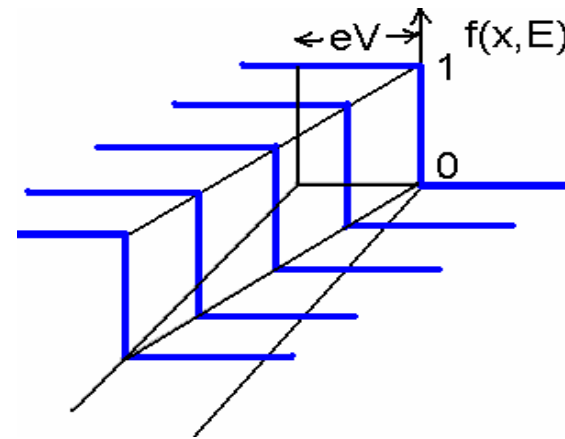
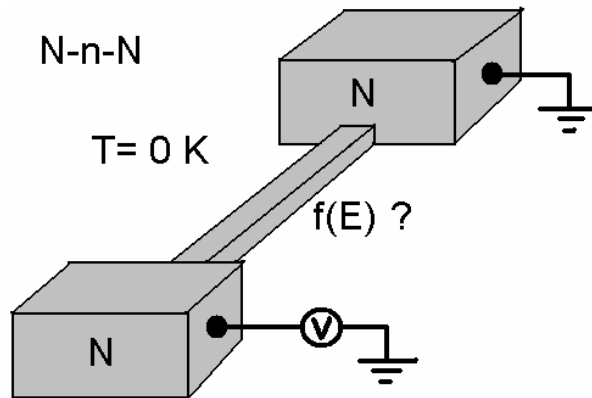
Kozub & Rudin, 1995

$$S_I = \frac{4}{RL} \iint dx dE f(x, E)(1 - f(x, E))$$



What does $f(x, E)$ look like?

Distribution function -- textbook case (no shot noise)



$$\tau_D = L^2/D$$

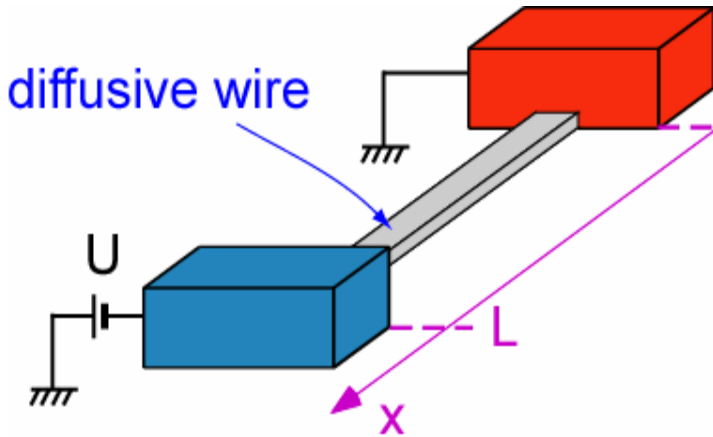
Assumes complete thermalization -- $t_D \gg t_{\text{electron-phonon}}$

Never true in mesoscopic metal samples at low T !

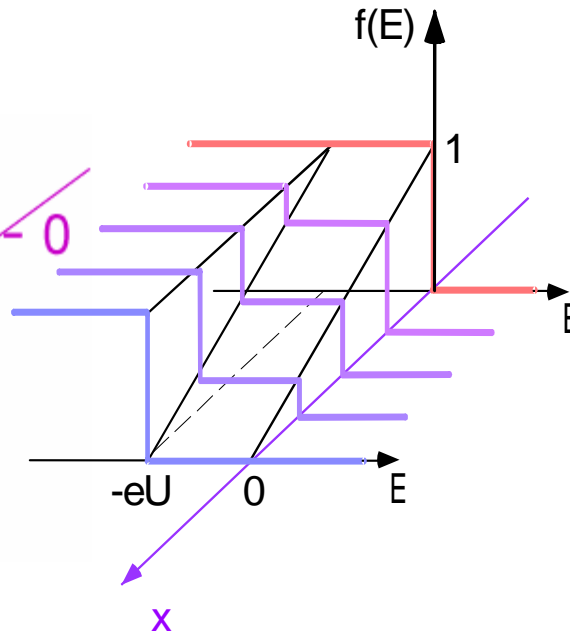
Distribution function for $\tau_D \ll \tau_{\text{electron-phonon}}$

free electrons

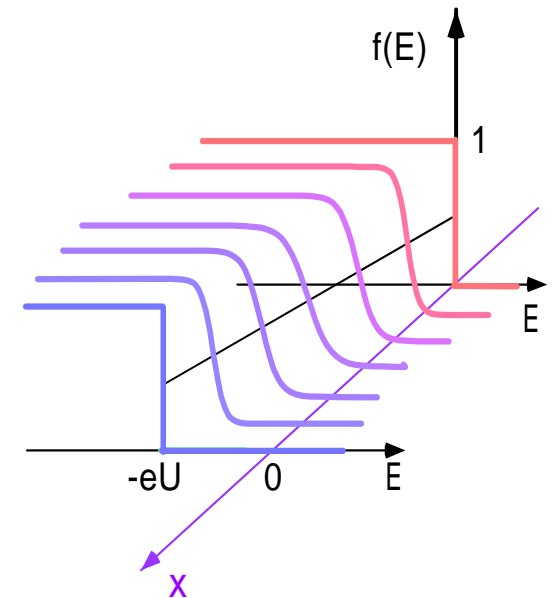
“hot” electrons



$$\tau_D = L^2/D$$



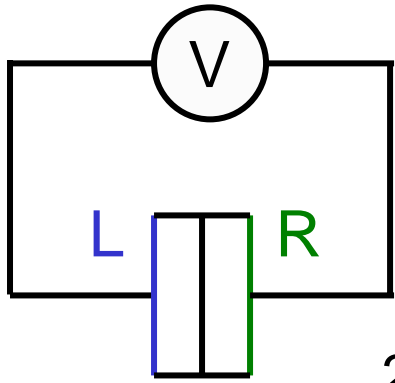
$\tau_D \ll \tau_{\text{interaction}}$



$\tau_D \gg \tau_{\text{interaction}}$

$f(x,E)$ shaped by energy exchange

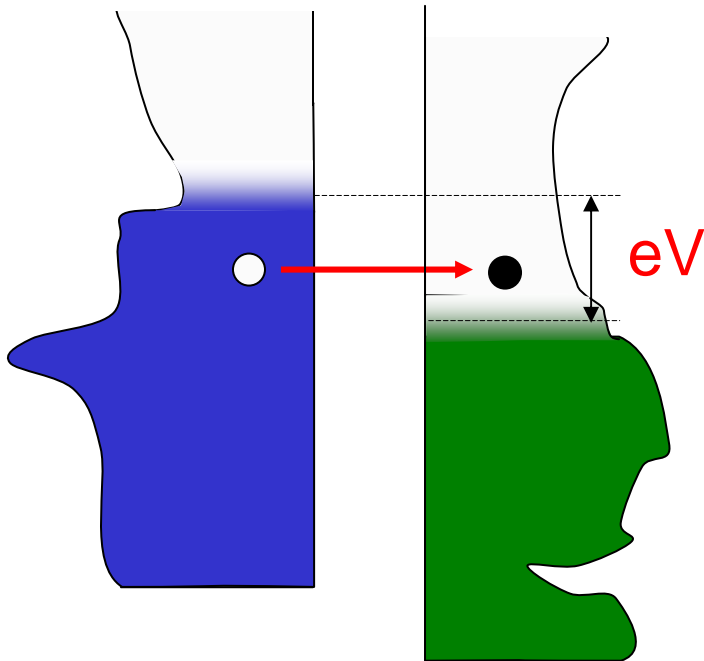
Aside 1: Current through a tunnel junction



$$I = e(\Gamma_{\rightarrow} - \Gamma_{\leftarrow})$$

$$\Gamma_{\rightarrow} = \frac{2\pi v_F^2}{\hbar} \int dE |\langle M \rangle|^2 n_L(E) n_R(E + eV) f_L(E) (1 - f_R(E + eV))$$

$$\Gamma_{\leftarrow} = \frac{2\pi v_F^2}{\hbar} \int dE |\langle M \rangle|^2 (1 - f_L(E)) f_R(E + eV)$$

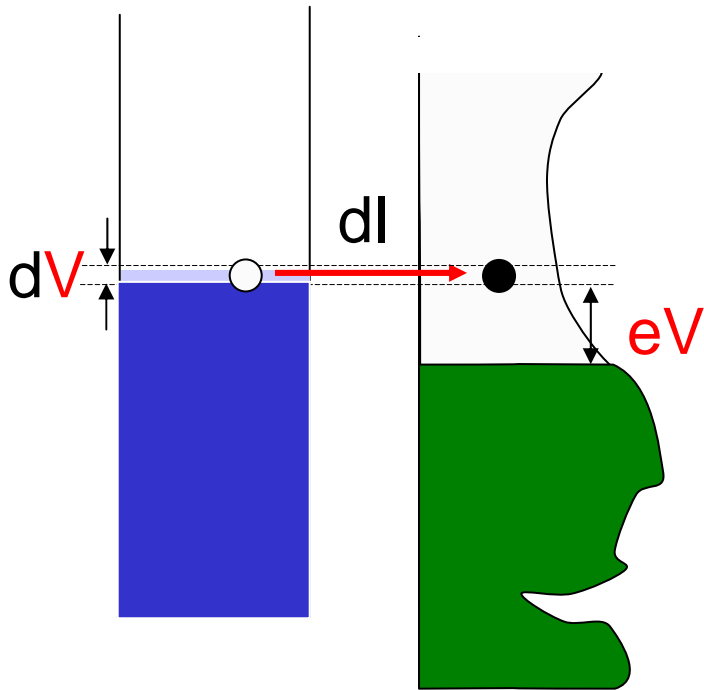
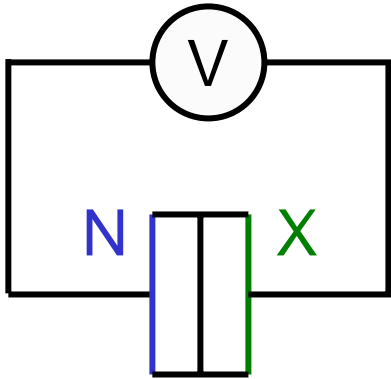


$$I = \frac{1}{eR_T} \int dE n_L(E) n_R(E + eV) \times (f_L(E) - f_R(E + eV))$$

NN junction: $n(E) = 1$ $f(E) = \begin{cases} 1 & E < 0 \\ 0 & E > 0 \end{cases}$

$$\Rightarrow I = \frac{V}{R_T}$$

Conductance of an N-X junction at T=0

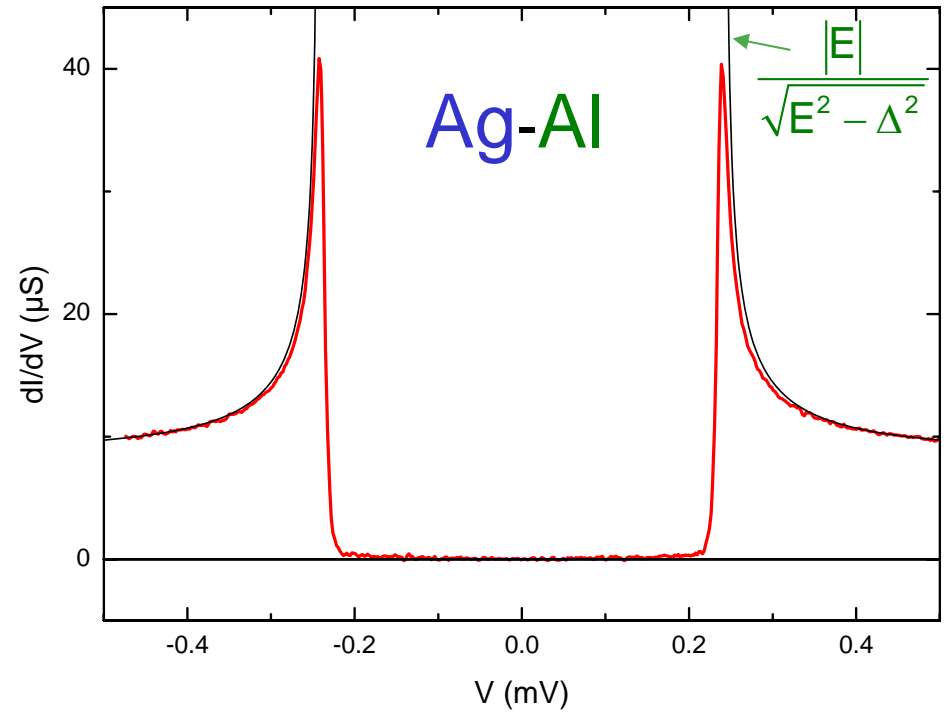
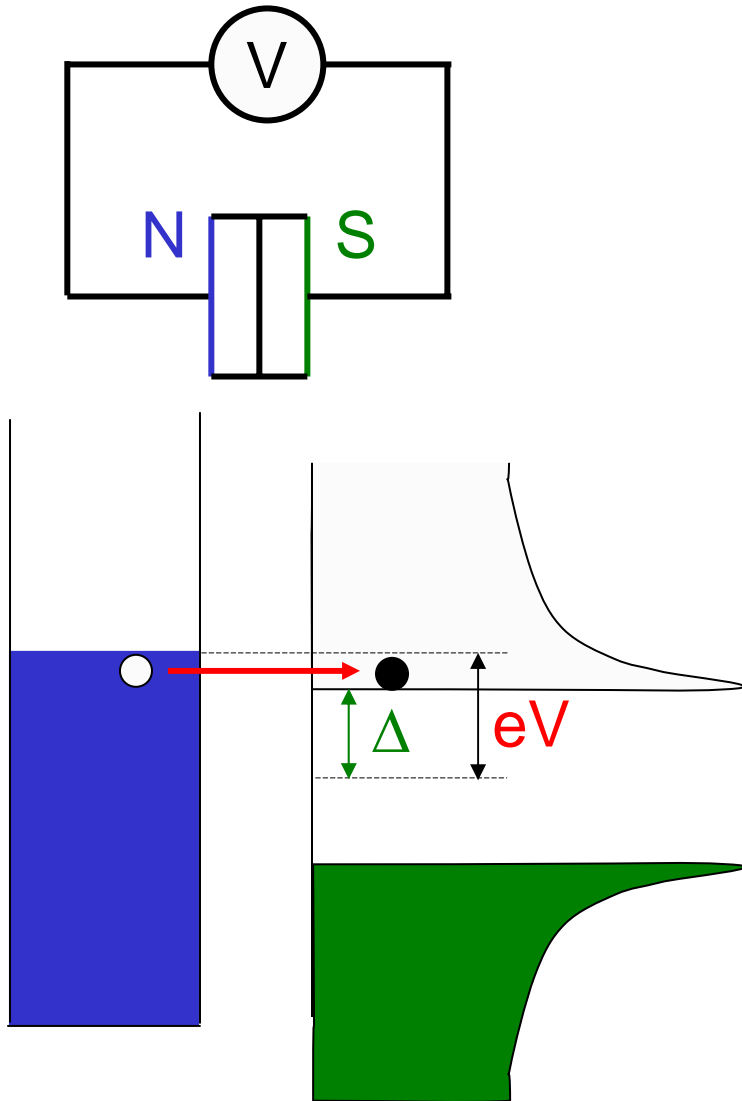


$$\begin{aligned} I &= \frac{1}{eR_T} \int dE n_L(E) n_R(E + eV) \\ &\quad \times (f_L(E) - f_R(E + eV)) \\ &= \frac{1}{eR_T} \int_{-eV}^0 dE n_X(E + eV) \\ &= \frac{1}{eR_T} \int_0^{eV} dE n_X(E) \end{aligned}$$

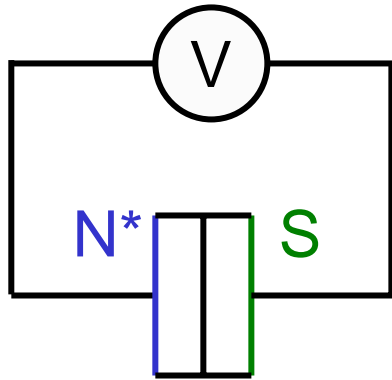
$$\frac{dI}{dV} = \frac{1}{R_T} n_X(eV)$$

Spectroscopy of n_X

How to measure $f(E)$: tunnel spectroscopy using an N-S junction

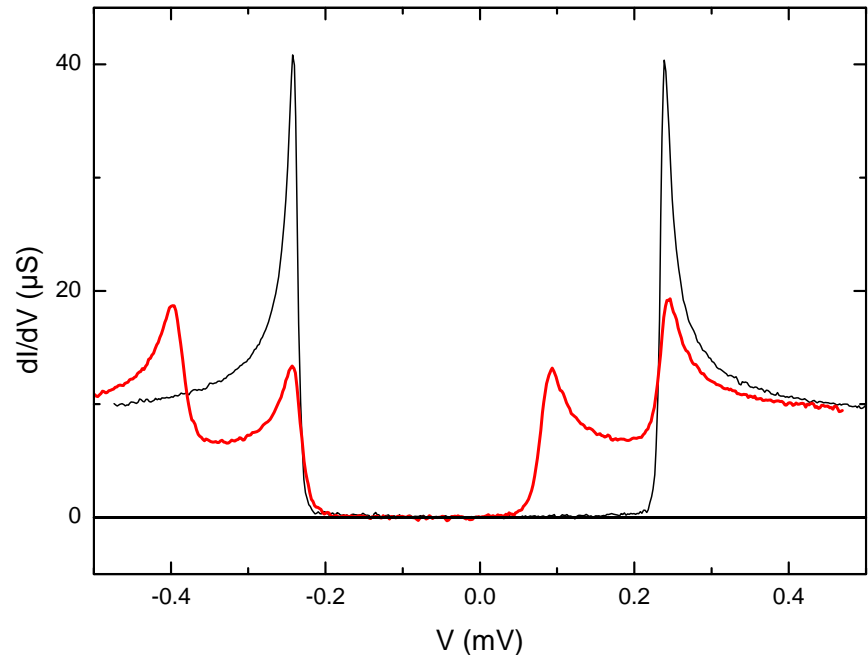
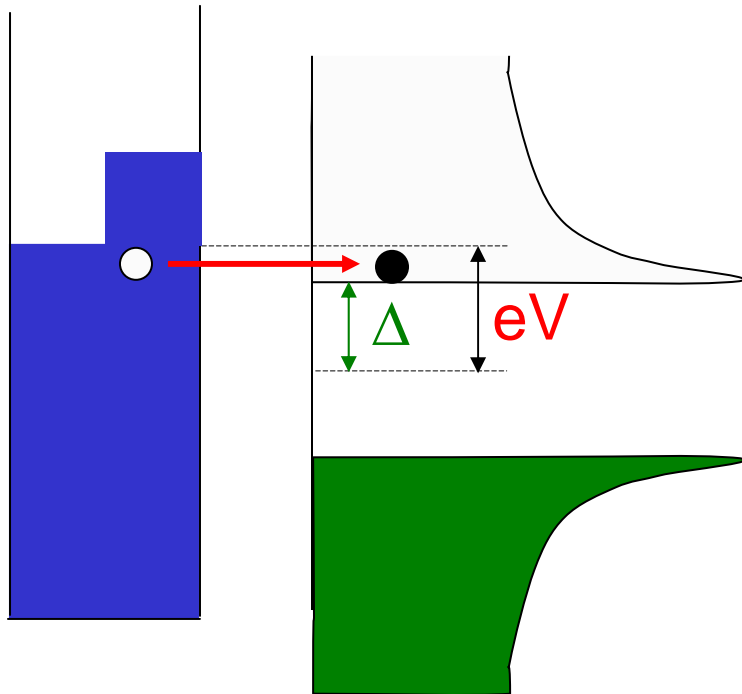


N out of equilibrium: spectroscopy of $f(E)$

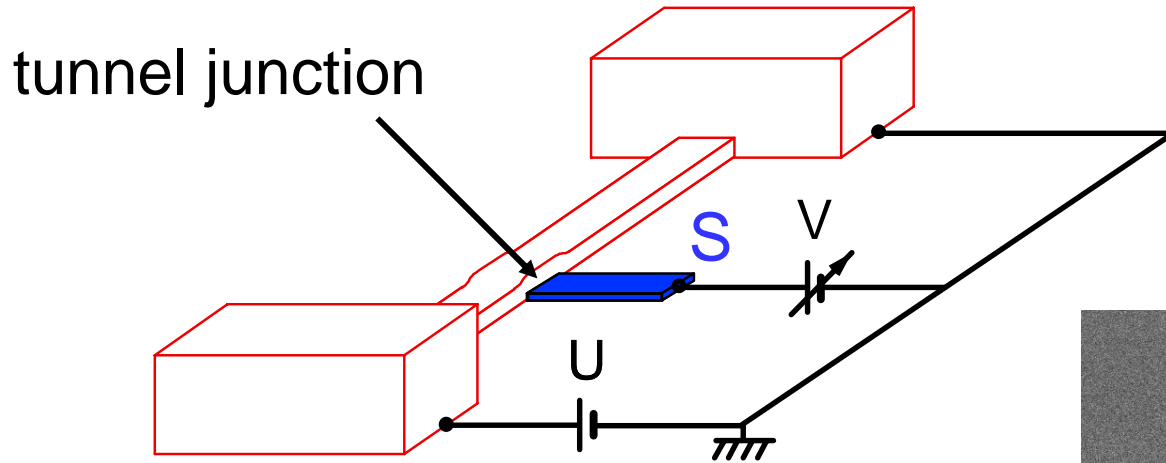


$$I = \frac{1}{eR_T} \int dE n_s(E) (f_N(E - eV) - f_S(E))$$

$$\frac{dI}{dV} = \frac{-1}{R_T} \int dE n_s(E) f'_N(E - eV)$$

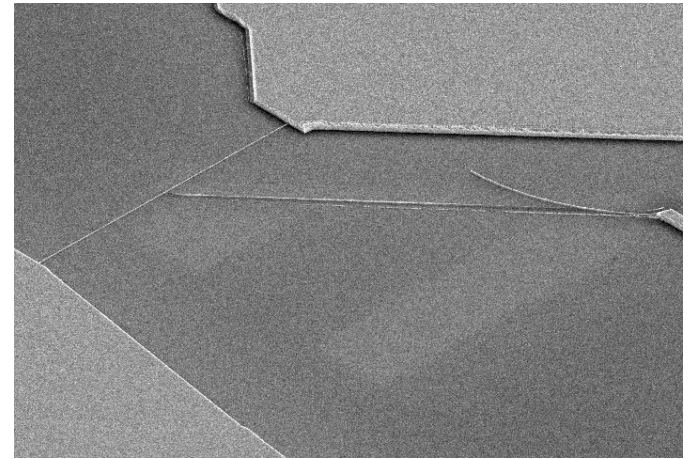


Experimental setup



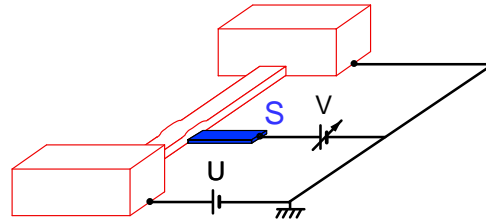
$L=5$ to $40 \mu\text{m}$

Diffusion time: $\tau_D = \frac{L^2}{D} = 1$ to 60 ns

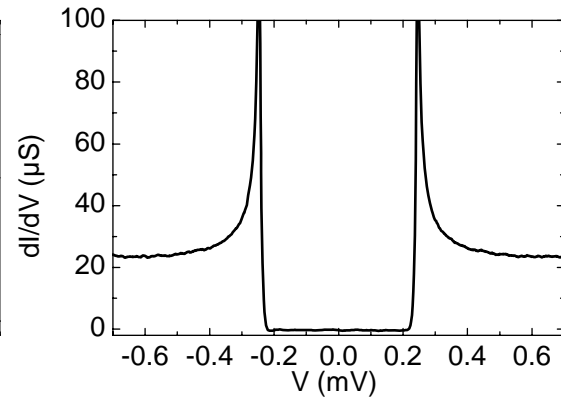
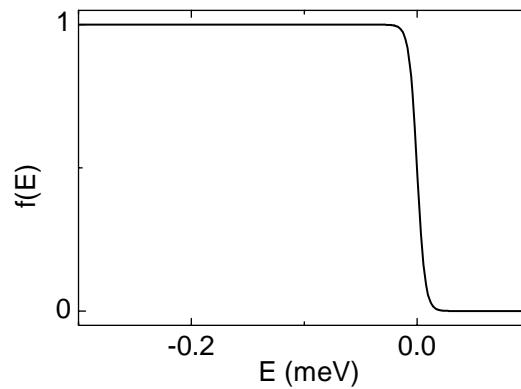


$$\frac{dI}{dV}(V) \xrightarrow[\text{deconvolution}]{\text{numerical}} f(E)$$

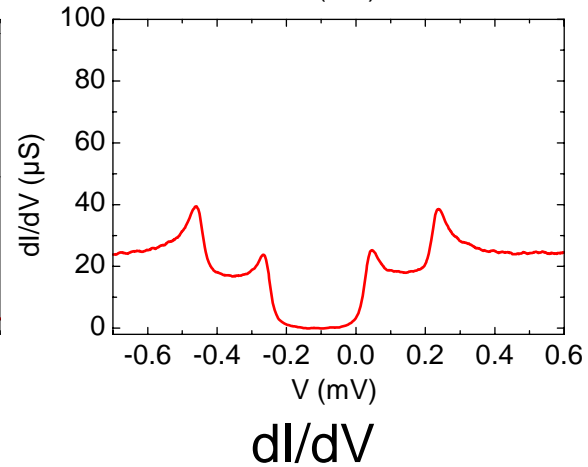
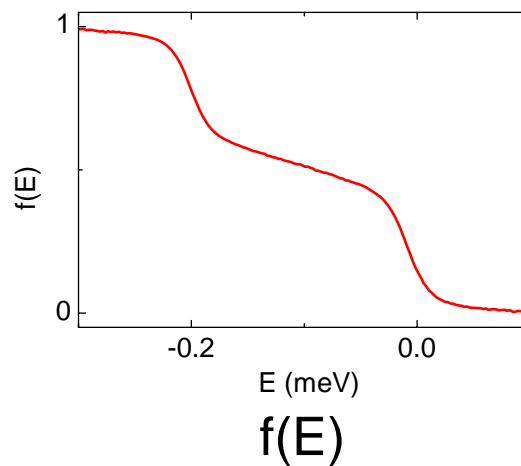
Summarize how to measure $f(E)$:



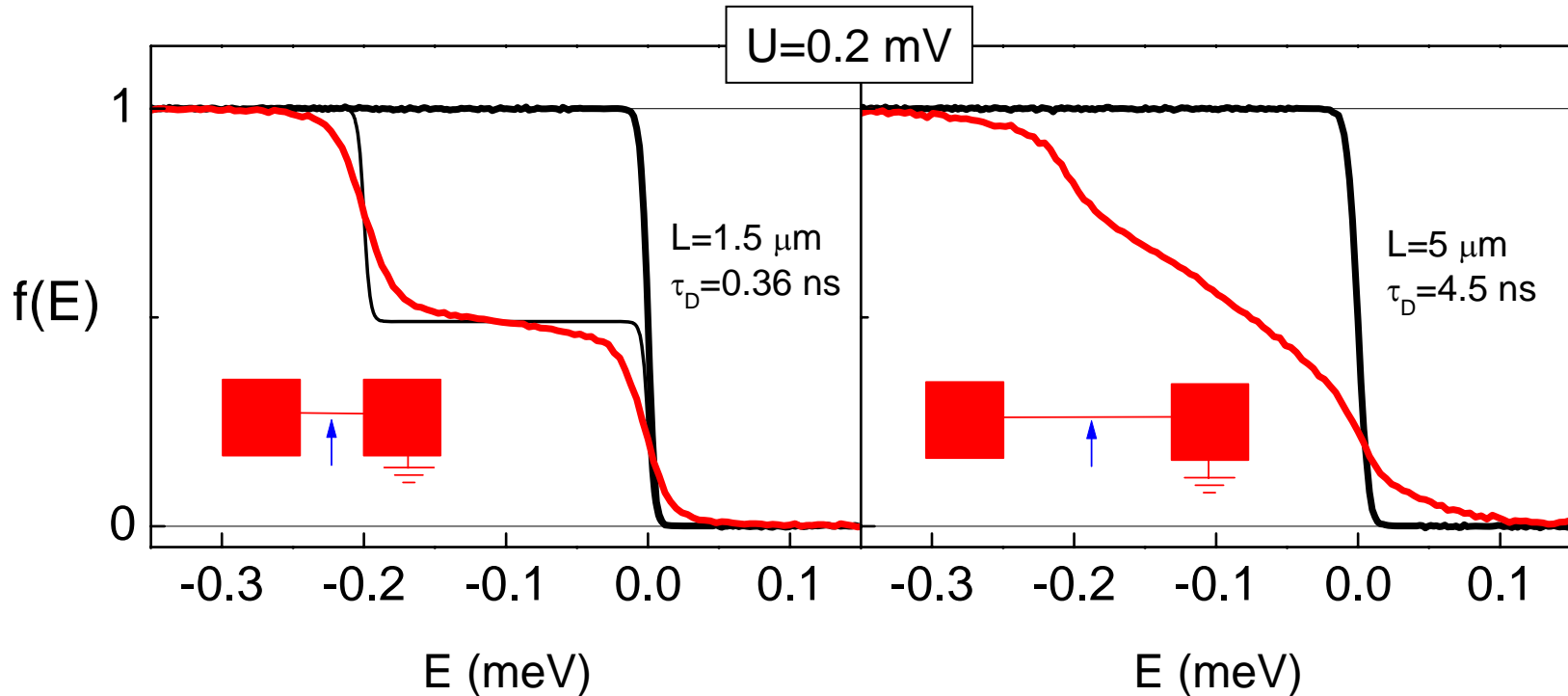
$U=0$ mV



$U=0.2$ mV

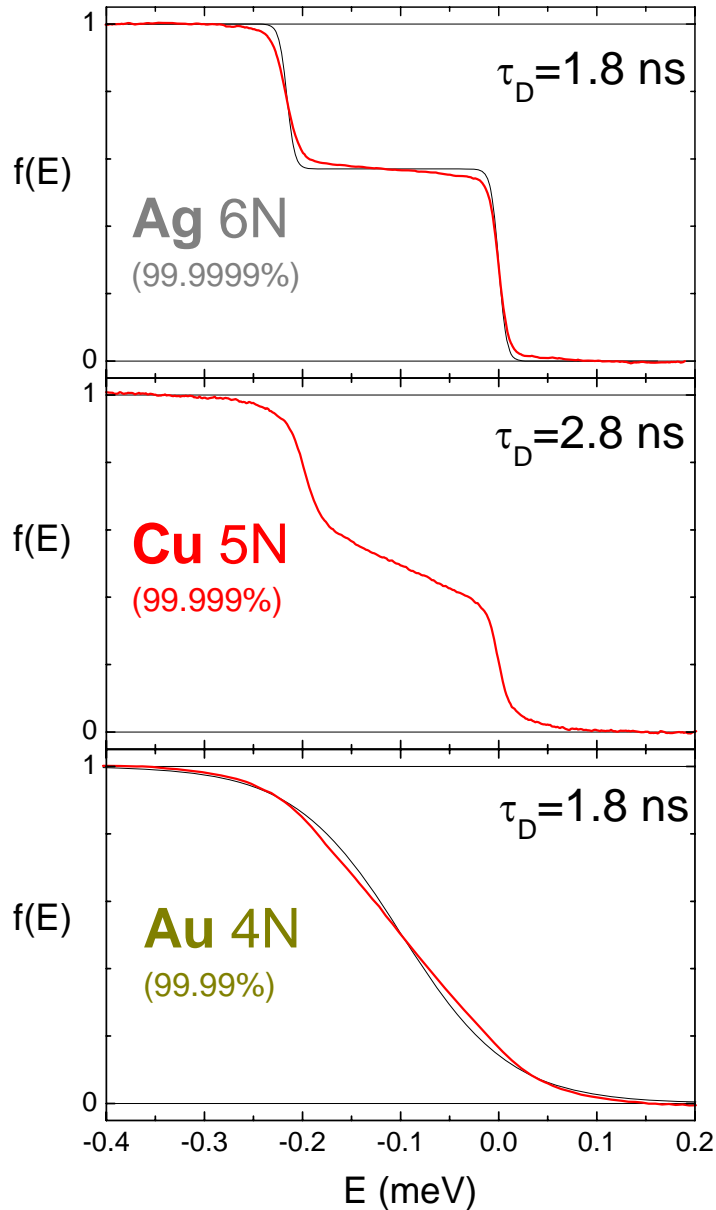


Effect of the diffusion time τ_D on $f(E)$



longer interaction time \Rightarrow more rounding

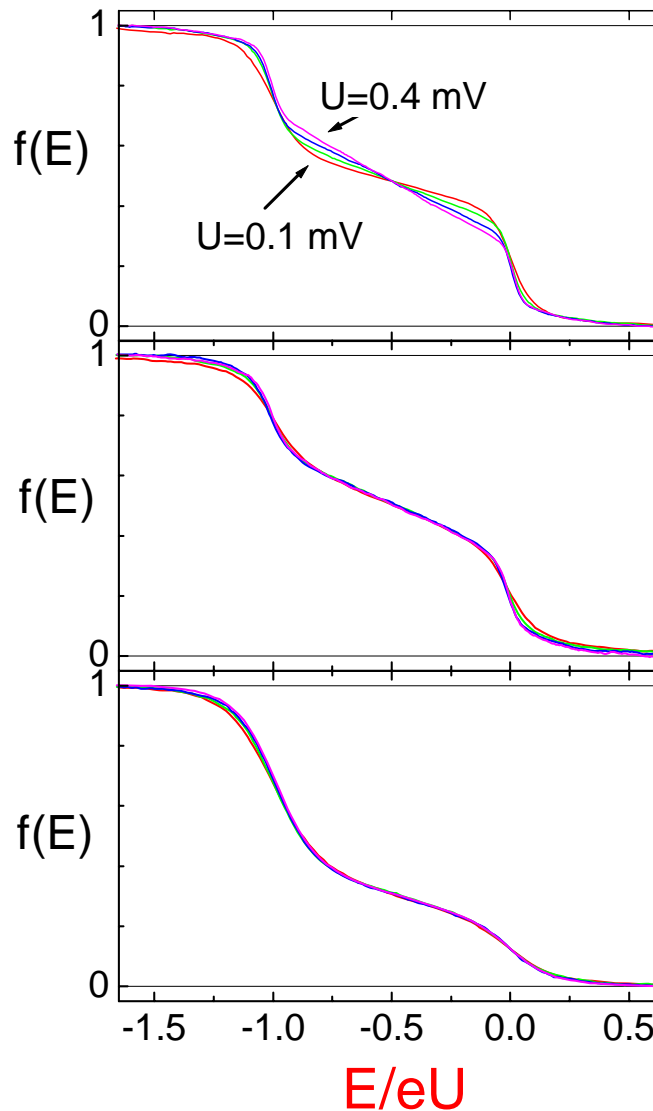
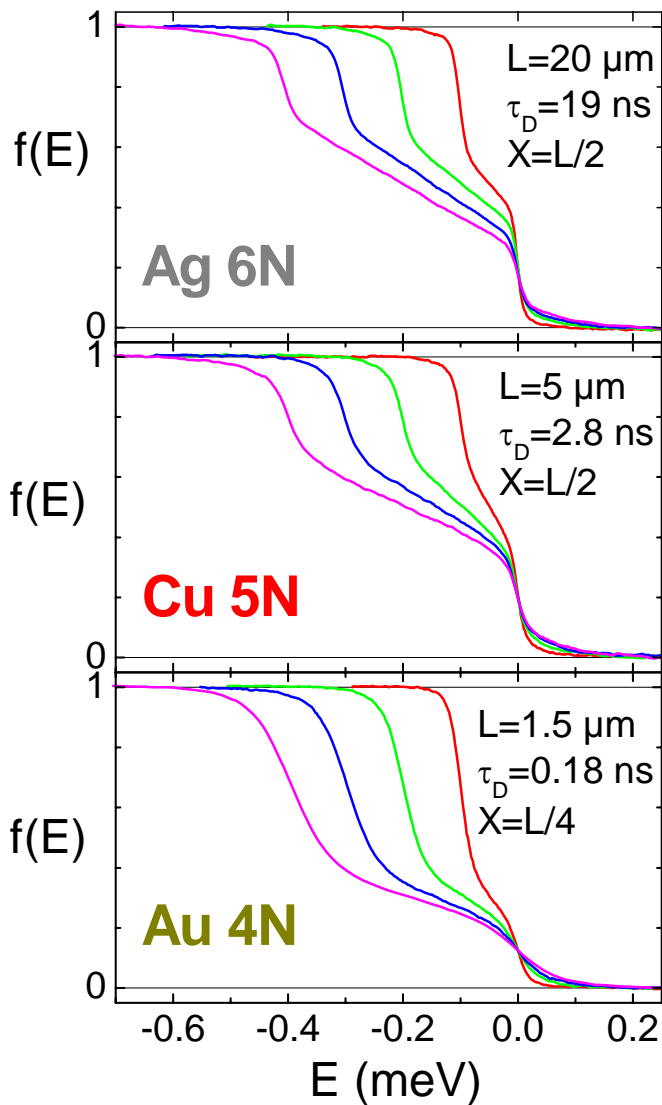
Compare strength of interactions



effect of material ?
effect of purity ?

Compare Dependence on U

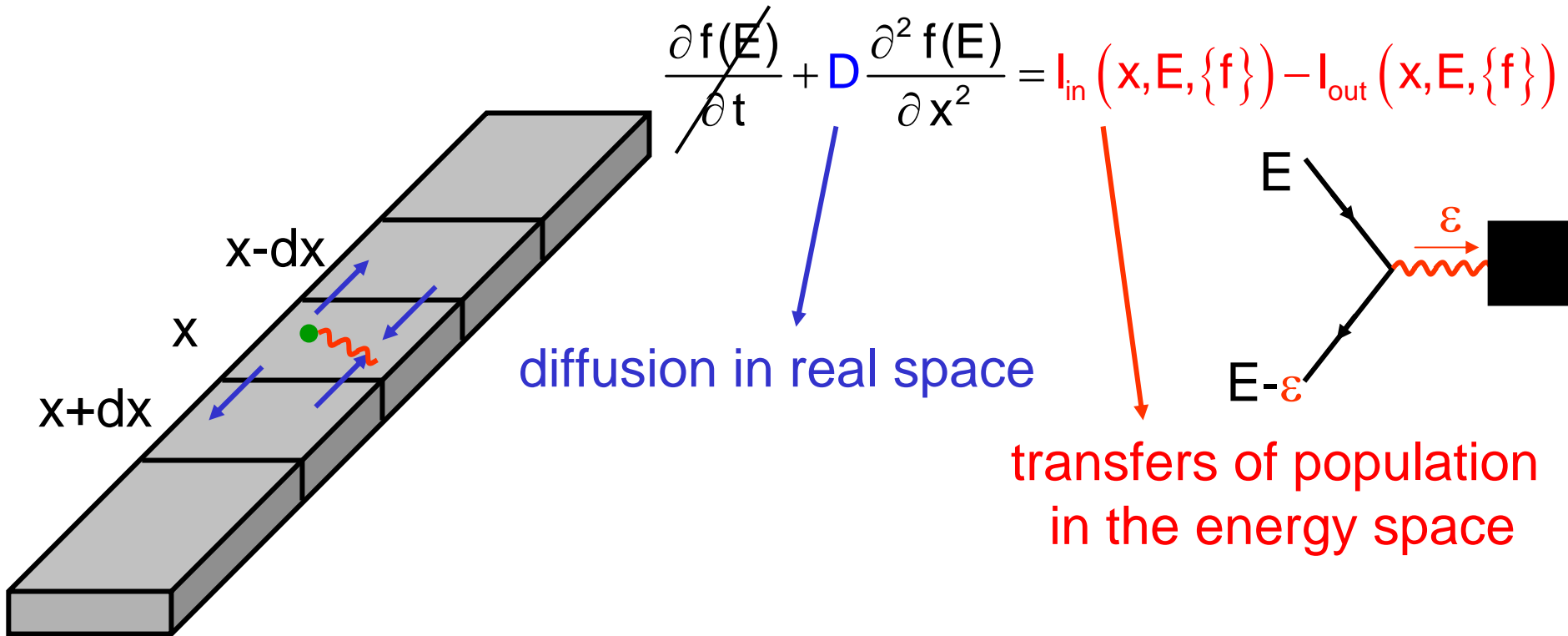
$U=0.1, 0.2, 0.3$ & 0.4 mV



Observe scaling law in **Au 4N** & **Cu 5N** but not in **Ag 6N**

Calculation of $f(x,E)$

Boltzmann equation in the diffusive regime (Nagaev, Phys. Lett. A, 1992):



Boundary conditions :

$$f_{x=0}(E) = f_{x=L}(E) = \text{Fermi function}$$

Calculation of $f(x, E)$

Boltzmann equation in the diffusive regime (Nagaev, Phys. Lett. A, 1992):

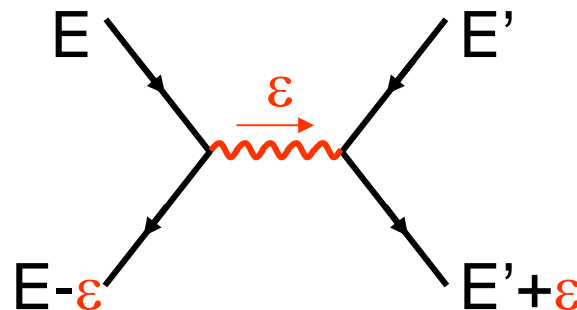
$$D \frac{\partial^2 f(E)}{\partial x^2} = I_{\text{in}}(x, E, \{f\}) - I_{\text{out}}(x, E, \{f\})$$

e-e interactions :

$$\frac{\mathcal{K}}{\varepsilon^{3/2}}$$

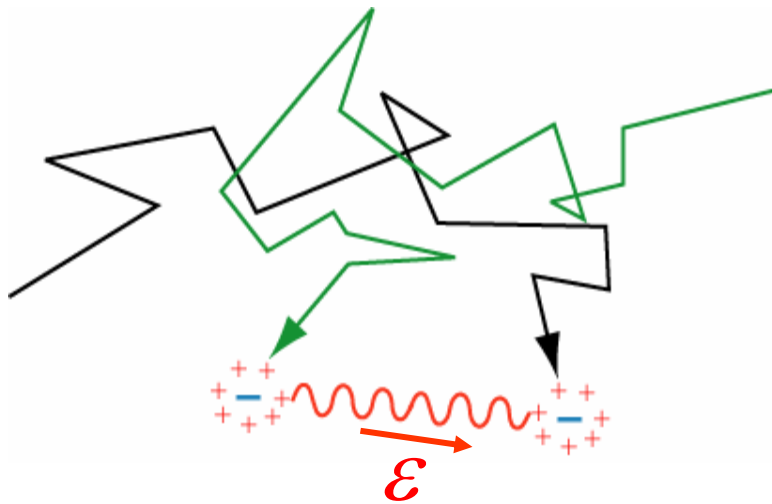
(Altshuler, Aronov, Khmelnitskii, 1982)

$$I_{\text{out}}(x, E, \{f\}) = \int dE' d\varepsilon \mathcal{K}(\varepsilon) f(E) [1 - f(E - \varepsilon)] f(E') [1 - f(E' + \varepsilon)]$$



Theory of screened Coulomb interaction in the diffusive regime

(Altshuler & Aronov, 1979)



ingredients:

polarisability \searrow

overlap \nearrow

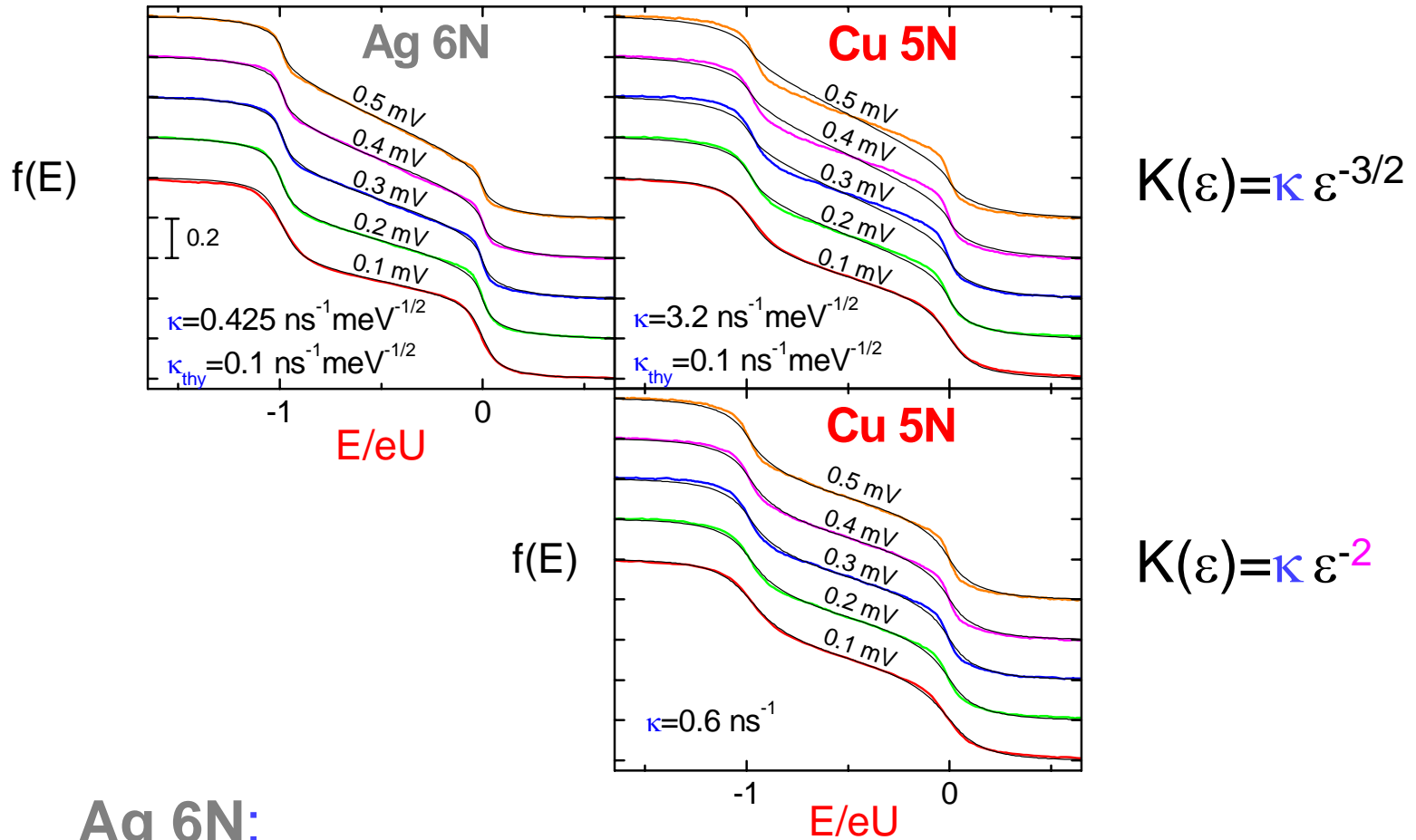
Prediction for 1D wire :

$$K(\varepsilon) = \frac{\kappa}{\varepsilon^{3/2}}$$

$$\left(\int \frac{dq}{D^2 q^4 + \omega^2} \right)$$

$$\kappa = \left(\sqrt{2D} \pi \hbar^{3/2} v_F S_e \right)^{-1}$$

Experiment vs. Theory



Ag 6N:

experiment agrees with theory

Cu 5N, Au 4N, Ag 5N:

- energy exchange stronger than predicted
- $K(\epsilon) = \kappa \epsilon^{-2}$ fits data

Comparison of the results of the two methods

	$\tau_\phi(T)$	$f(E)$
$\text{Ag}_{6\text{N}}$	$\propto T^{-2/3}$	$K(\varepsilon) = \frac{\kappa}{\varepsilon^{3/2}}$
$\text{Ag}_{5\text{N}}$ $\text{Cu}_{6\text{N},5\text{N},4\text{N}}$ $\text{Au}_{4\text{N}}$	saturation	fast relaxation rates $K(\varepsilon) \propto \frac{1}{\varepsilon^{3/2}}$

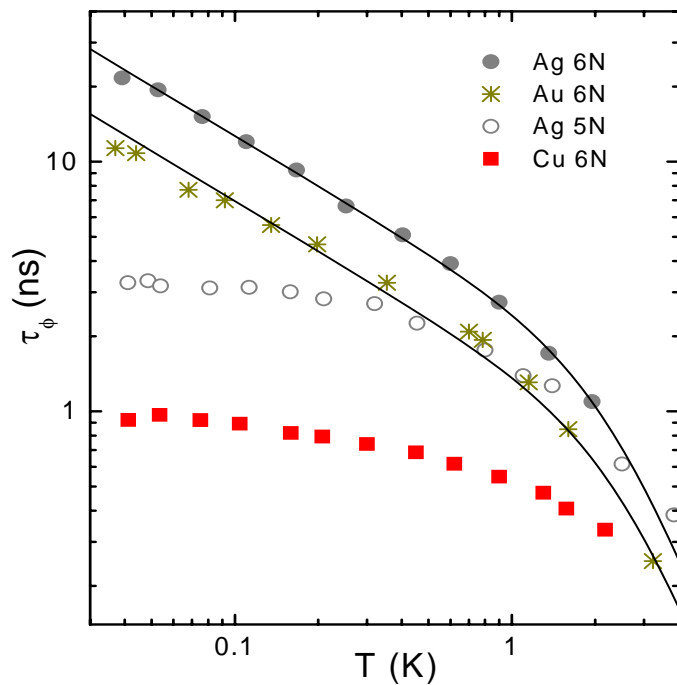
Comparison of the results of the two methods

	$\tau_\phi(T)$		$f(E)$
Ag _{6N}	$\propto T^{-2/3}$	Coulomb interactions	$K(\epsilon) = \frac{K}{\epsilon^{3/2}}$
Ag _{5N} Cu _{6N,5N,4N} Au _{4N}	saturation	Other mechanism	fast relaxation rates $K(\epsilon) \propto \frac{1}{\epsilon^{3/2}}$

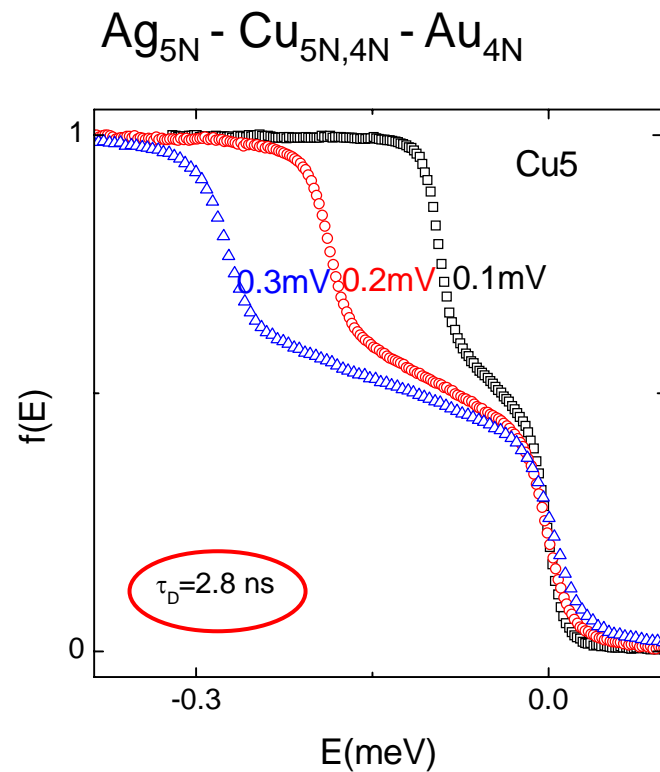
→ ROLE OF RESIDUAL IMPURITIES ?

The two puzzles

$\tau_\phi(T)$ measurements



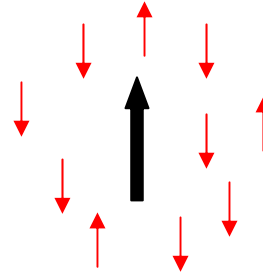
$f(E)$ measurements



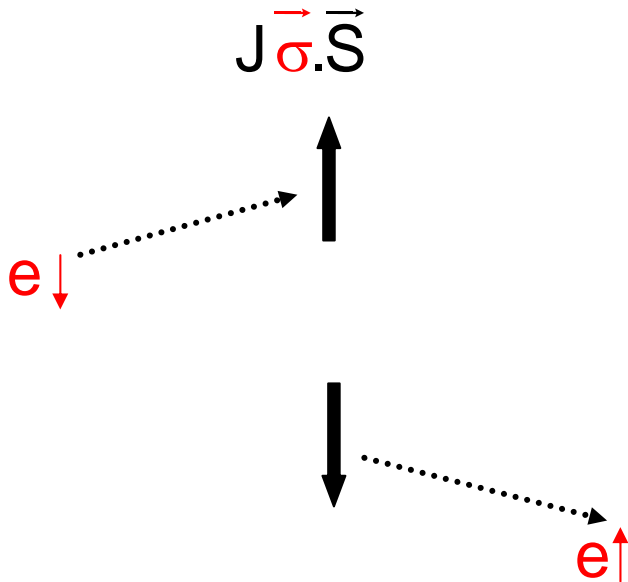
Anomalous interactions in the less pure samples

The Kondo effect again

Collective effect:

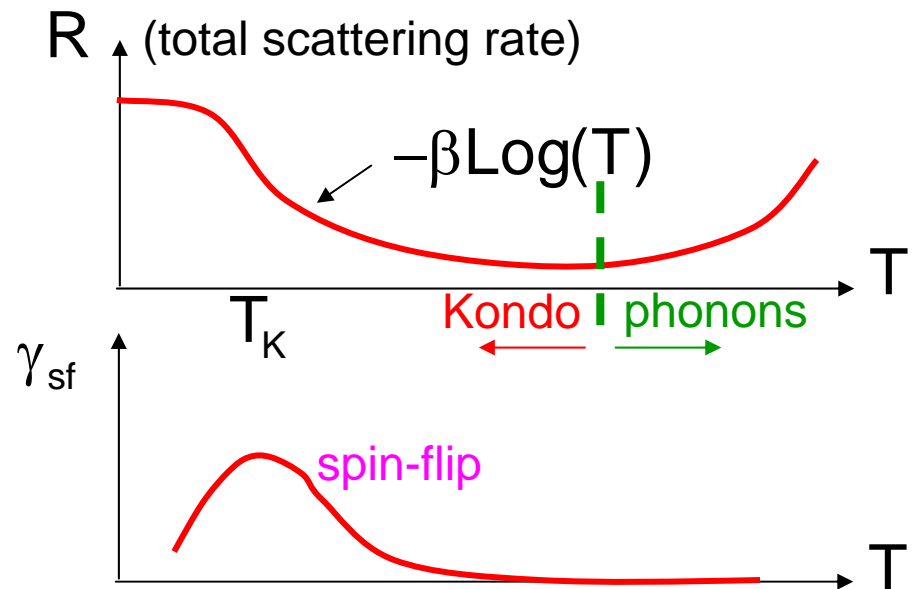


Formation of a singlet spin state
 $k_B T_K \approx E_F e^{-1/vJ}$

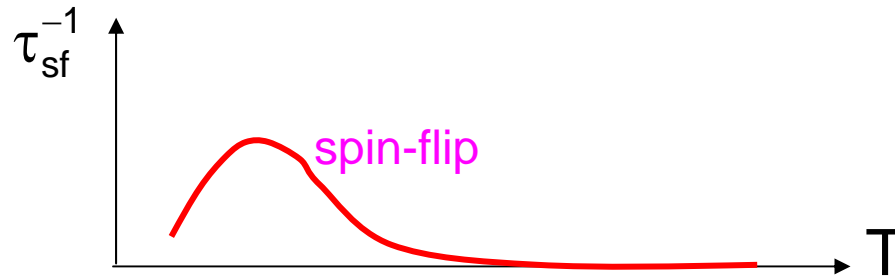


Spin-flip scattering

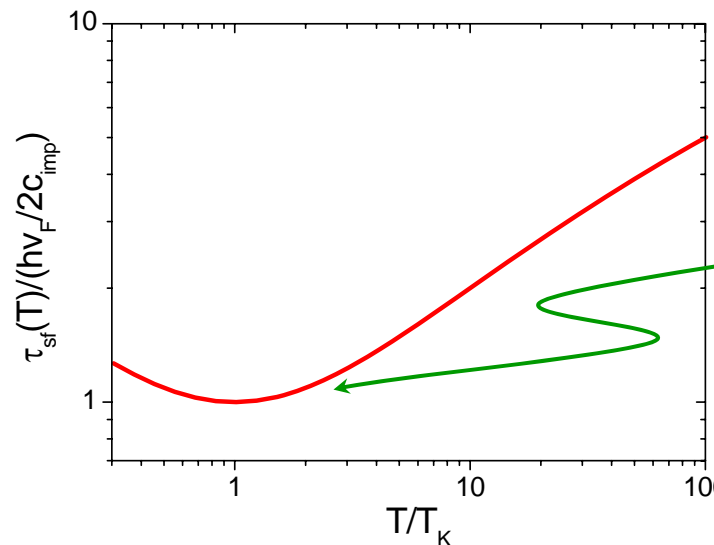
- ⇒ increased resistivity
- ⇒ reduction of τ_ϕ



Nagaoka-Suhl expression of the spin-flip scattering rate near T_K



$$\frac{1}{\tau_{sf}} = \frac{c_{mag}}{\pi \hbar v_F} \frac{\pi^2 S(S+1)}{\pi^2 S(S+1) + \ln^2(T/T_K)}$$

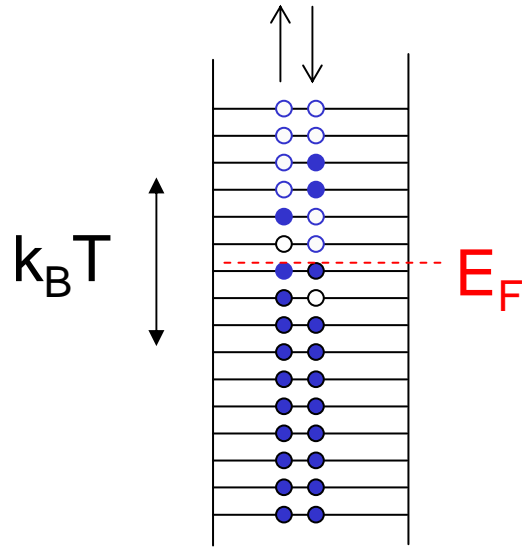


Weak temperature dependence near T_K !!



Link to $\tau_{\phi}(T)$ saturation?

Comparison of τ_{sf} and τ_K



$v_F k_B T$ concentration of electrons that can spin-flip

C_{imp} concentration of magnetic impurities

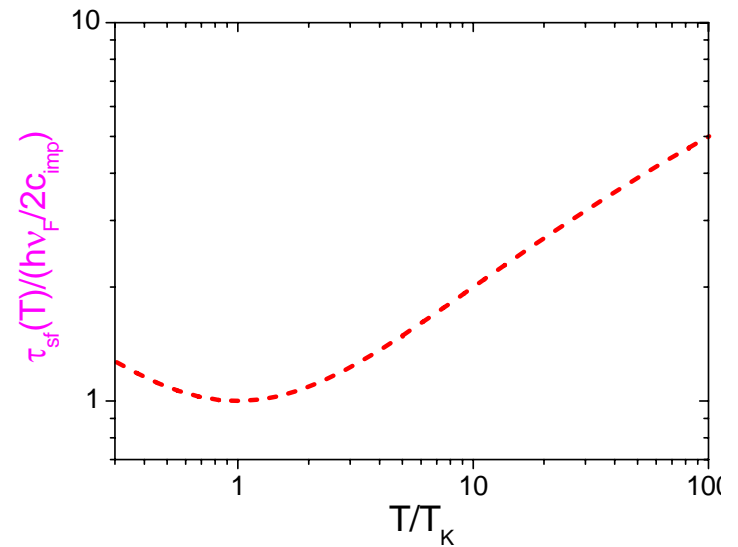
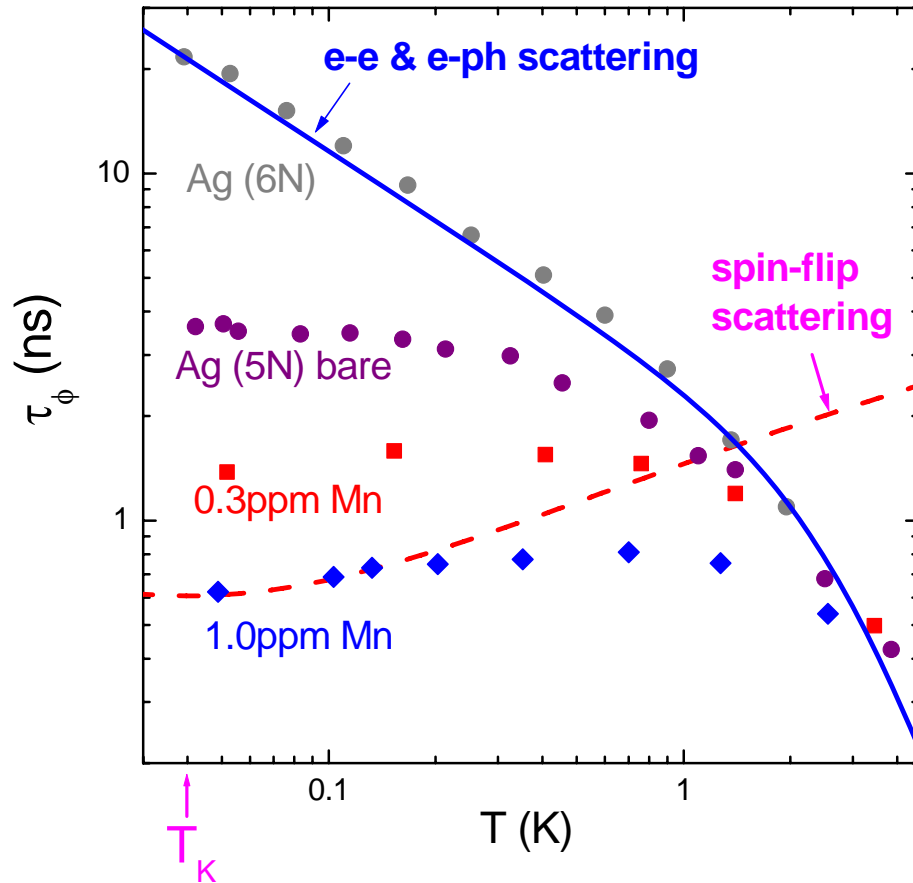
If $v_F k_B T > C_{imp}$: $\tau_K < \tau_{sf}$

$$\frac{1}{\tau_{\phi}} = \frac{1}{\tau_{ee}} + \frac{1}{\tau_{e-ph}} + \frac{1}{\tau_{sf}}$$

Numerically,
for Au, Ag, Cu, ...

$T > 40 \text{ mK} \times c_{imp} (\text{ppm})$

Effect of magnetic impurities on τ_ϕ

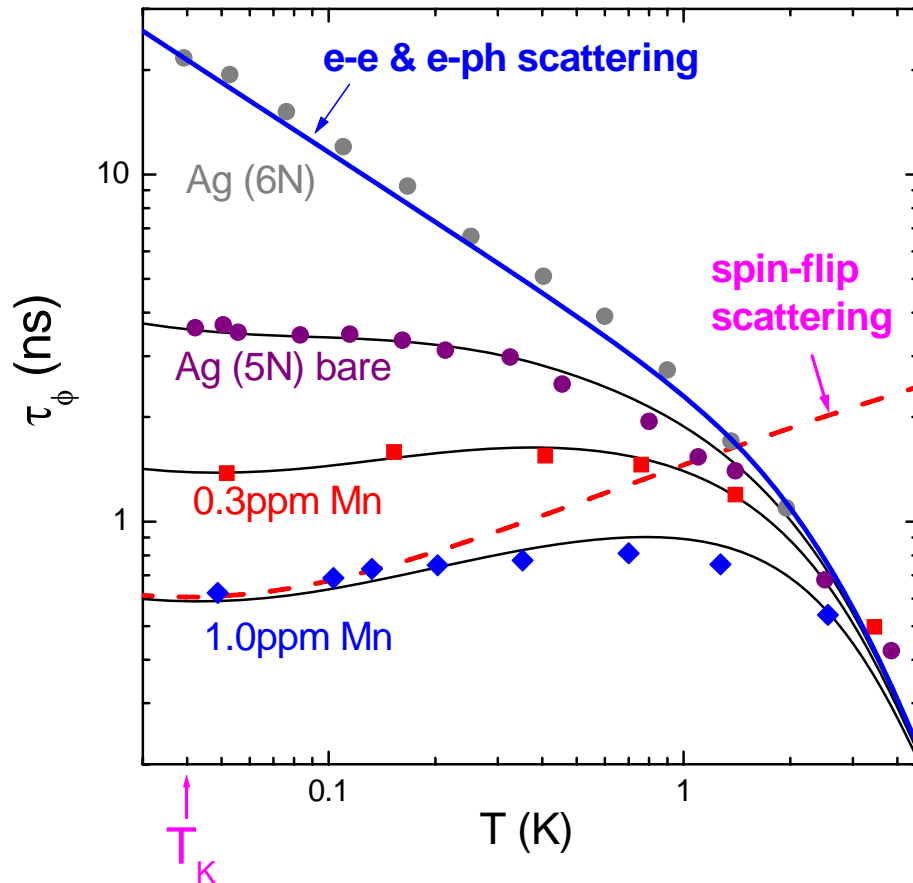


Spin-flip rate peaks at T_K :

$$\tau_\phi(T_K) = \frac{0.6 \text{ ns}}{c_{imp} \text{ (ppm)}}$$

$$\frac{1}{\tau_\phi} = \frac{1}{\tau_{ee}} + \frac{1}{\tau_{e-ph}} + \frac{1}{\tau_{sf}}$$

Effect of magnetic impurities on τ_ϕ



F. Pierre *et al.*,
PRB **68**, 0854213 (2003)

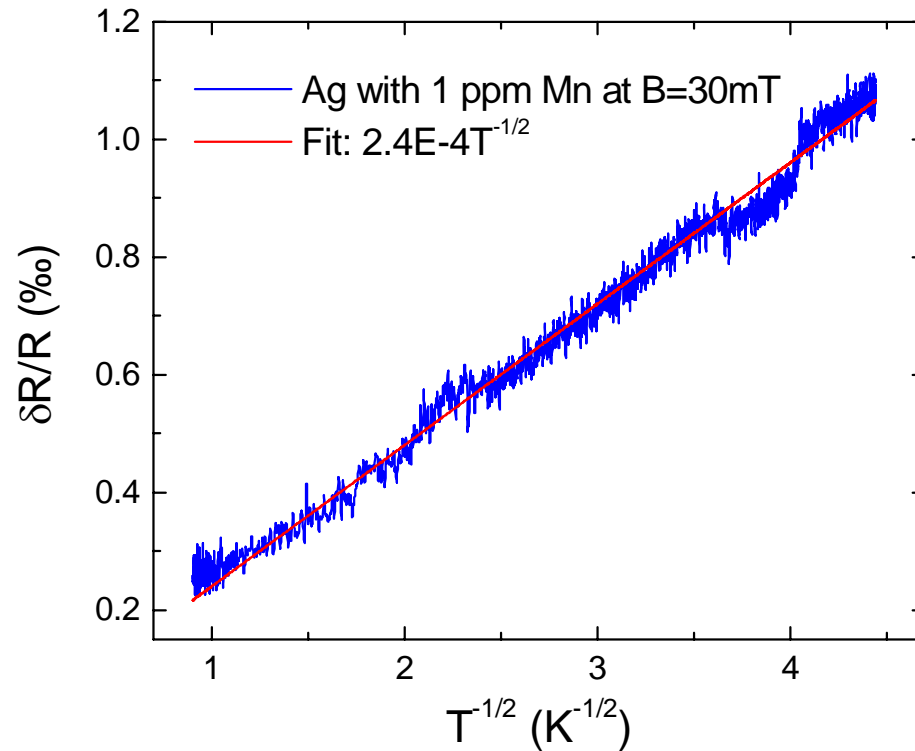
Fit parameters:

Ag(5N) bare: 0.13 ppm
+ 0.3 ppm : 0.40 ppm
+ 1 ppm : 0.96 ppm

Above T_K : partial compensation of e-e and s-f

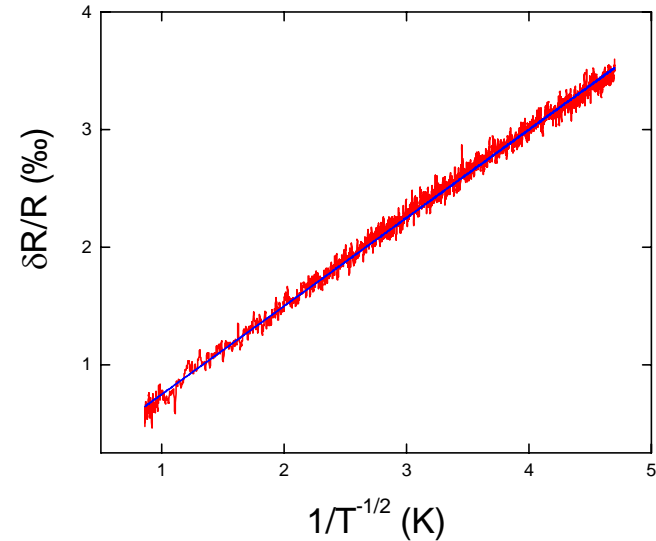
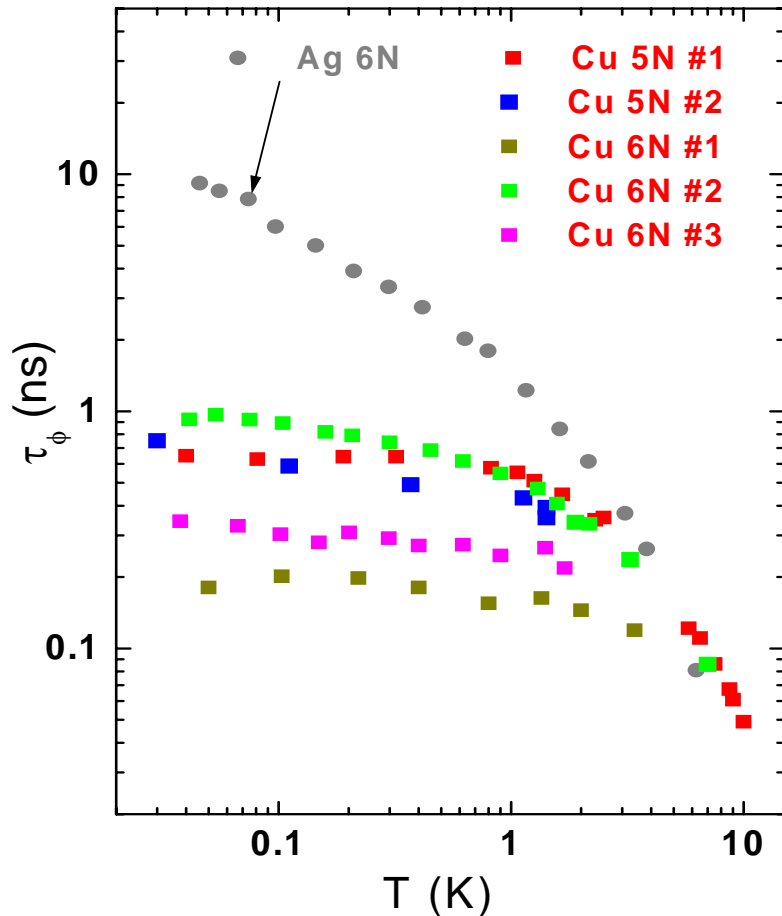
→ apparent saturation

Why can't we just detect magnetic impurities with $R(T)$ (the original Kondo effect)?



1 ppm of Mn is invisible in $R(T)$
(hidden by e-e interactions)

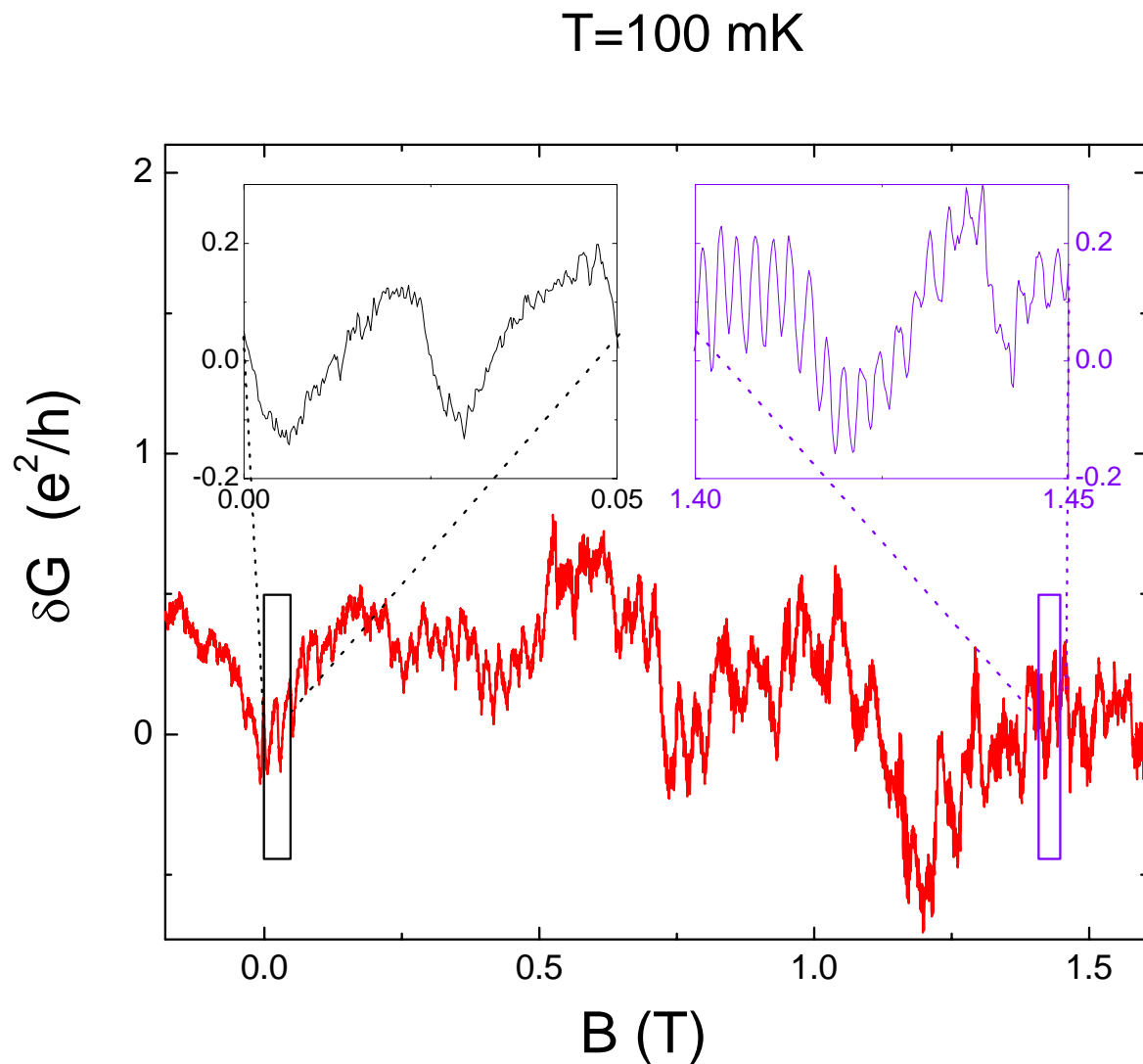
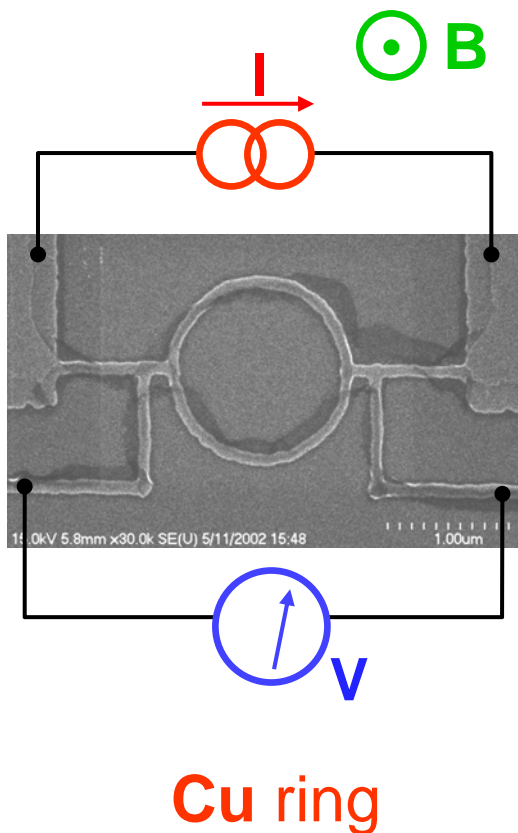
Source material purity vs. sample purity: Cu samples



Magnetic impurities
are invisible in $R(T)$

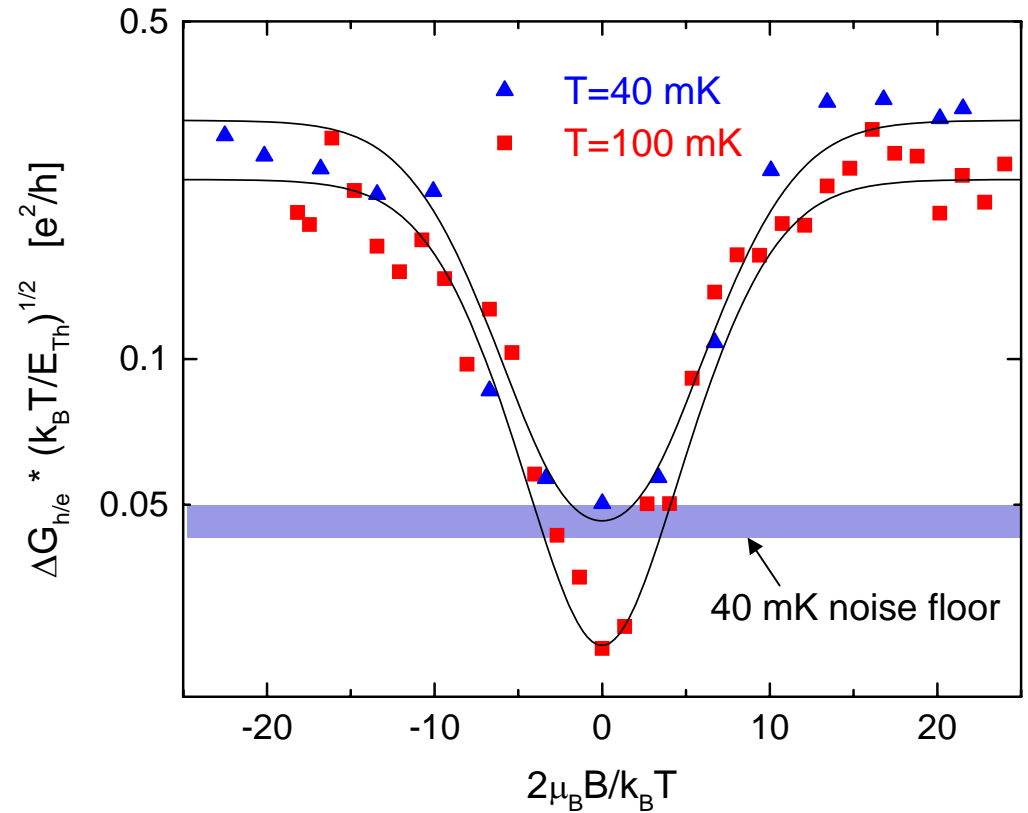
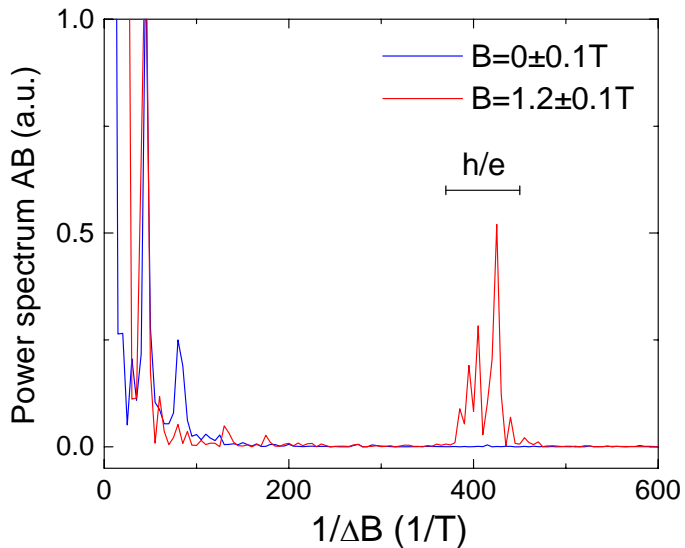
- In all **Cu** samples $\tau_\phi(T)$ saturates at low T
- $\tau_\phi(T)$ is strongly reduced but shows no dip

Measure $\tau_\phi(B)$ from Aharonov-Bohm oscillations



A.B. Oscillations vs. Magnetic Field

Fourier Transform
($T=100$ mK)

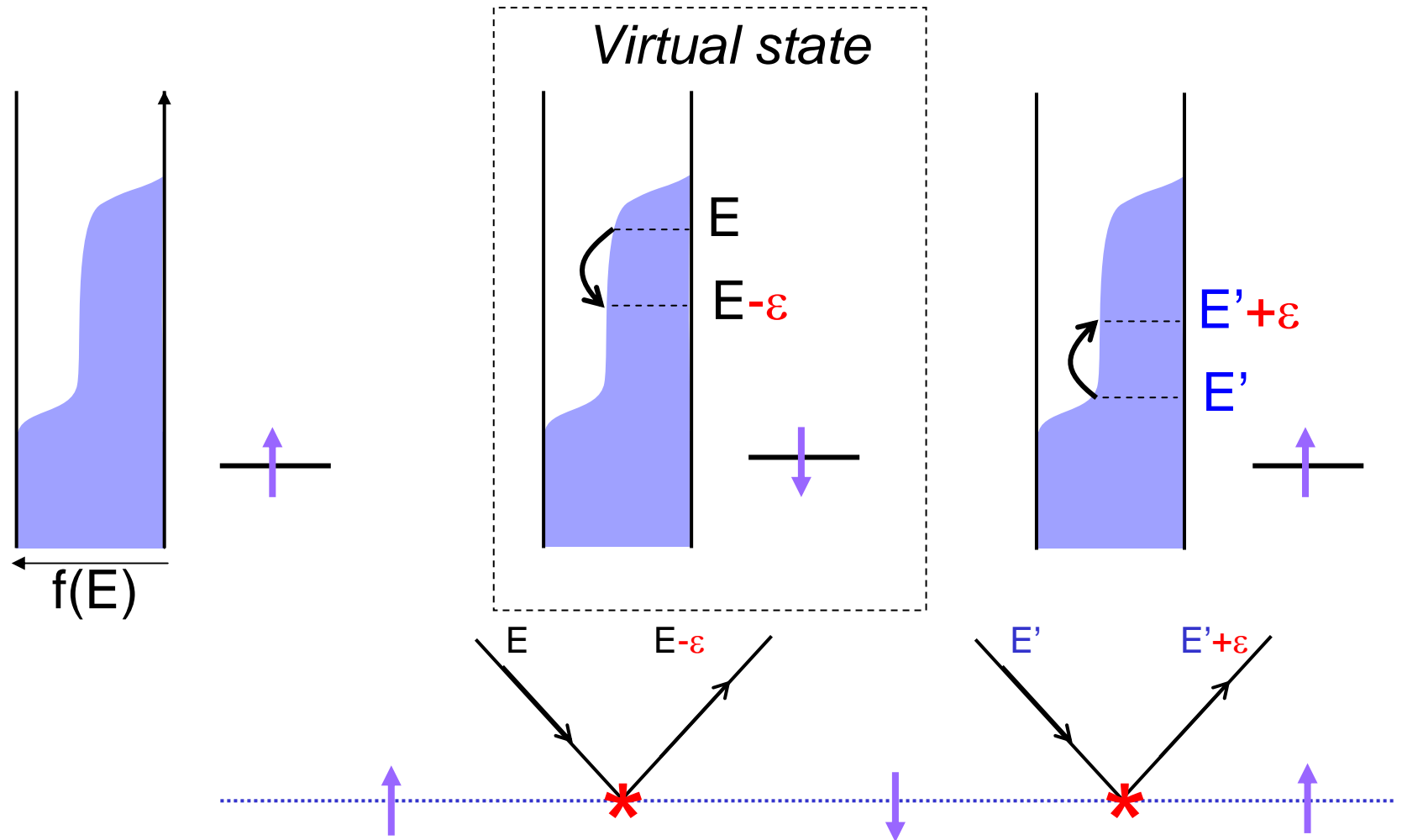


**AB oscillations increase with B
⇒ presence of magnetic “impurities” !**

What about energy exchange ?

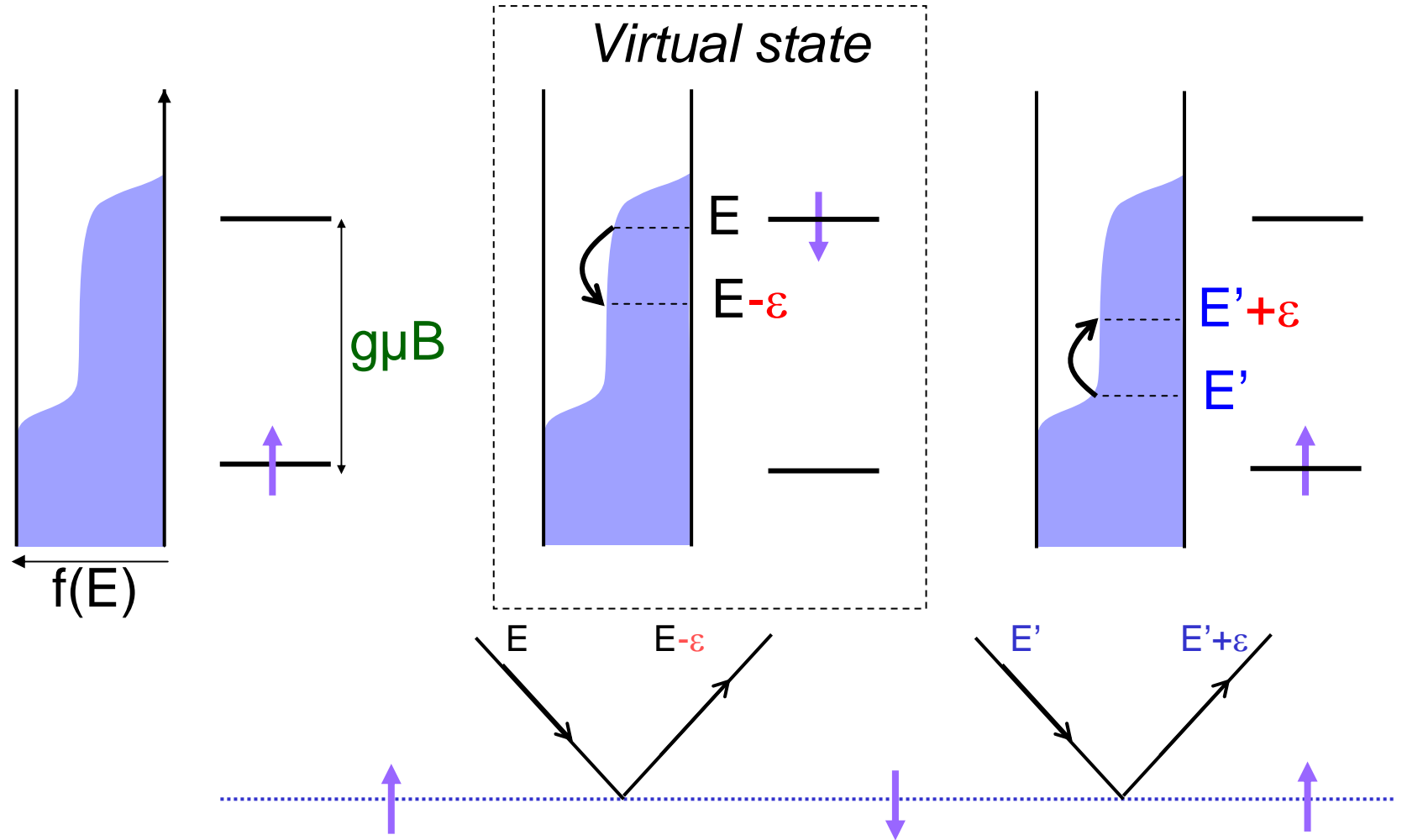
Energy exchange mediated by magnetic impurities

Kaminski and Glazman, PRL **86**, 2400 (2001)



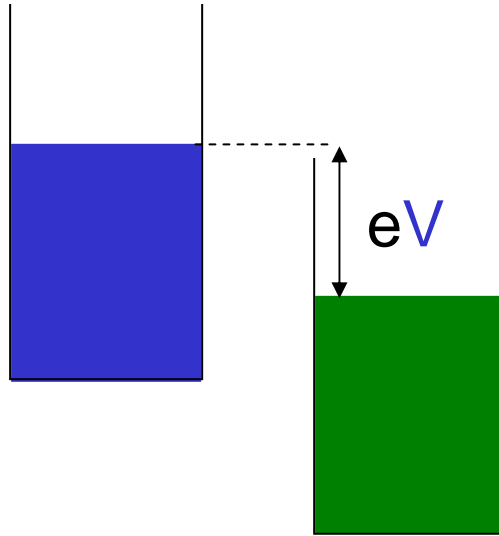
Reinforced by Kondo effect

Energy exchange mediated by magnetic impurities vanishes when $g\mu_B B \gg eU$

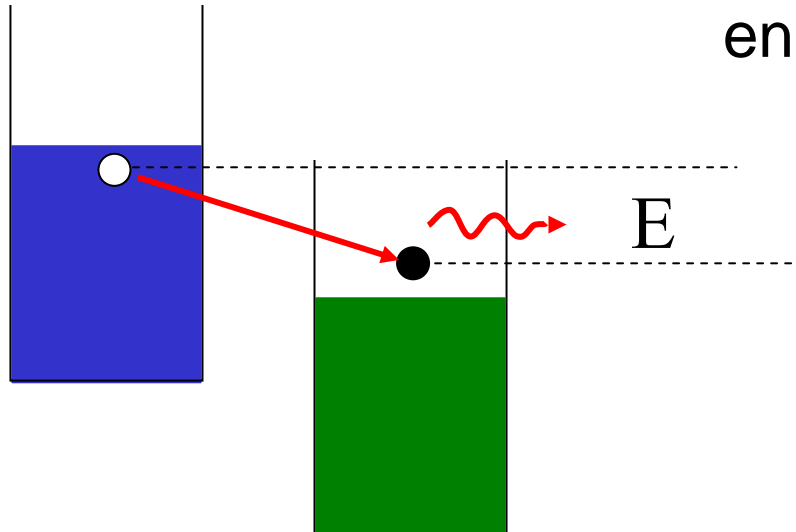


Aside 2: Inelastic tunneling

initial state:

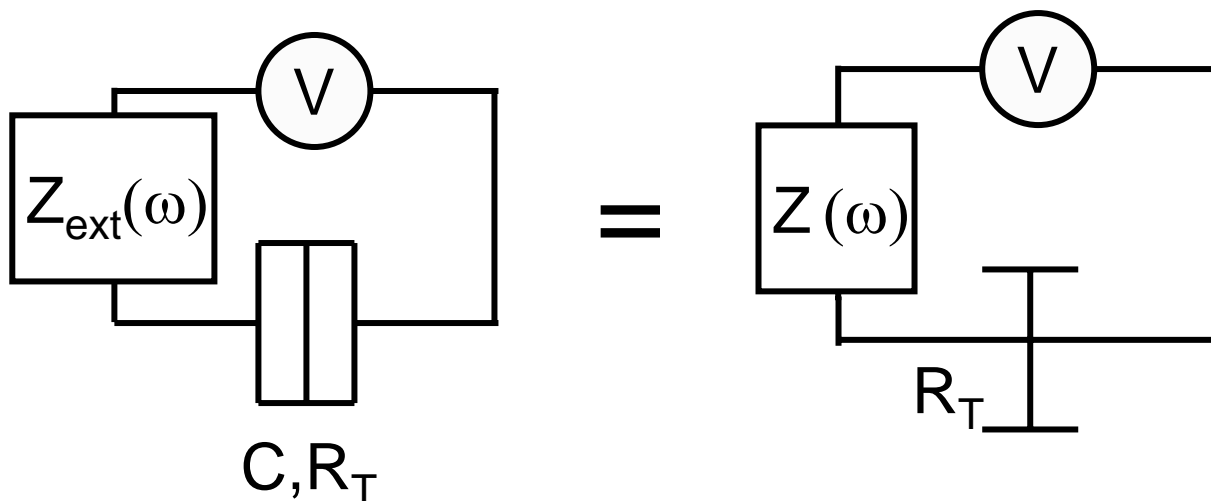


final state:



$P(E)$ = probability to give energy E to environment

P(E) depends on environmental impedance



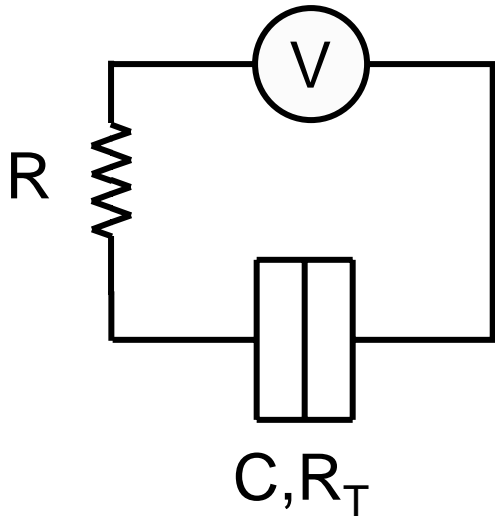
At $T=0$, one obtains :

$$\frac{dI}{dV} = \frac{1}{R_t} \int_0^{eV} P(E) dE$$

$$P(E) = \frac{1}{2\pi\hbar} \int e^{iEt/\hbar + J(t)} dt$$

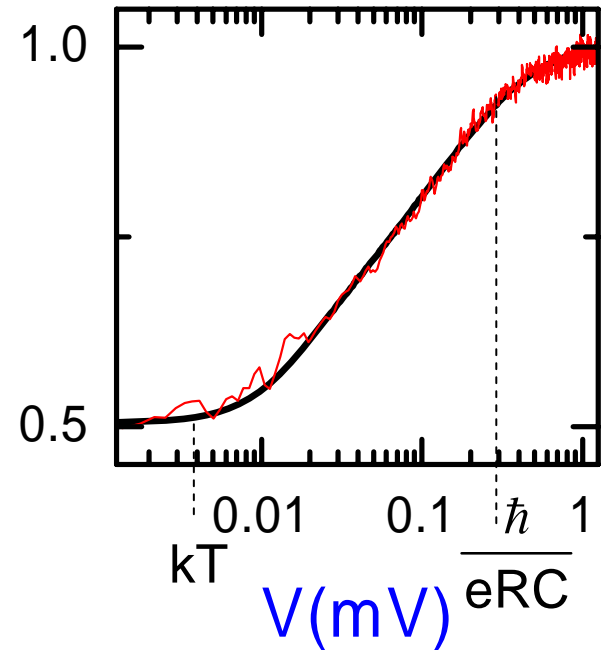
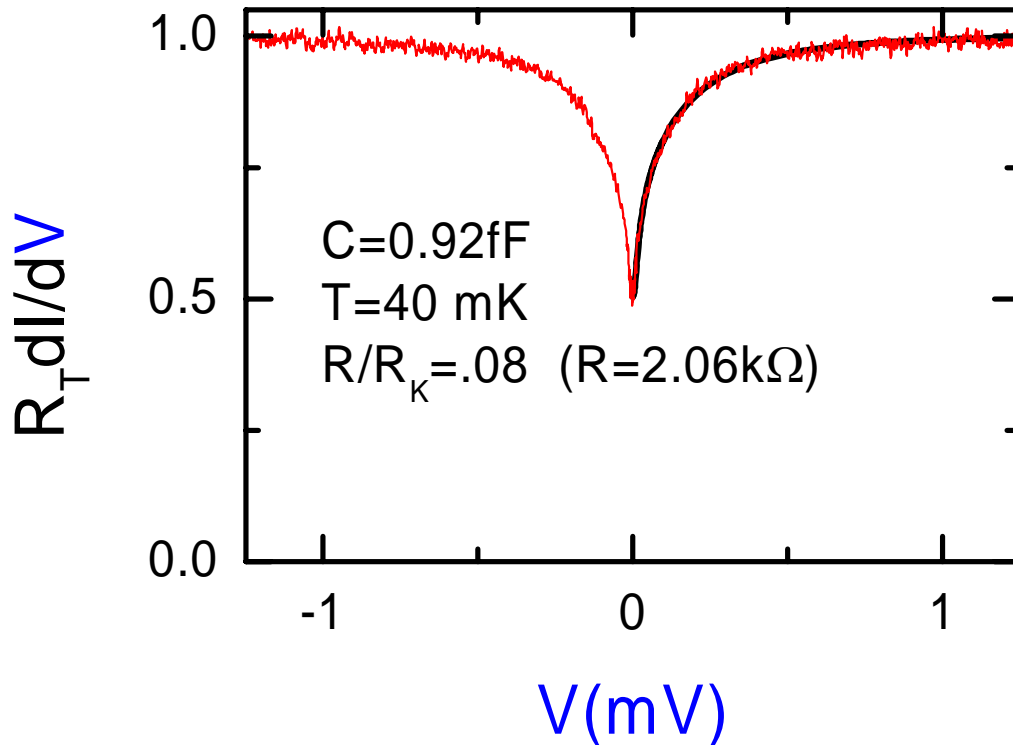
$$J(t) = 2 \int_0^{+\infty} \frac{d\omega}{\omega} \frac{\text{Re}[Z(\omega)]}{R_K} (e^{-i\omega t} - 1)$$

Resistive environment

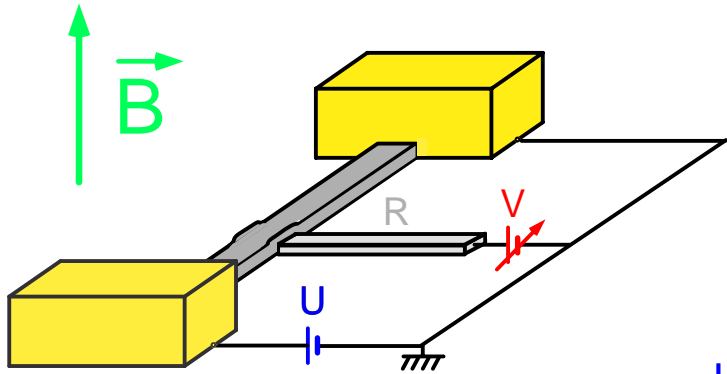


For $eV < \frac{\hbar}{RC}$

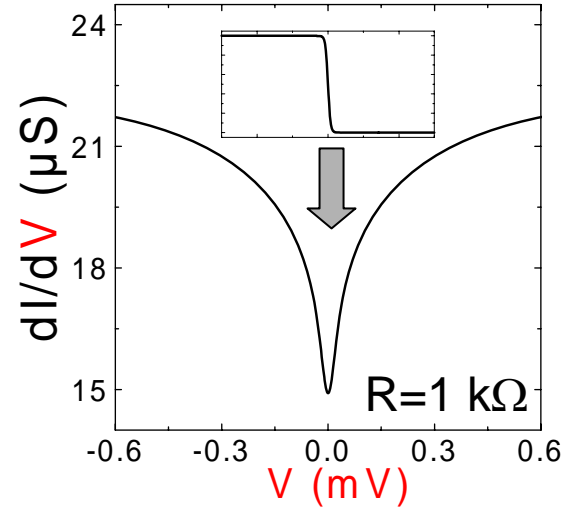
$$\frac{dI}{dV} \propto \left(V \frac{2R}{R_K} + \text{cst.} \right)$$



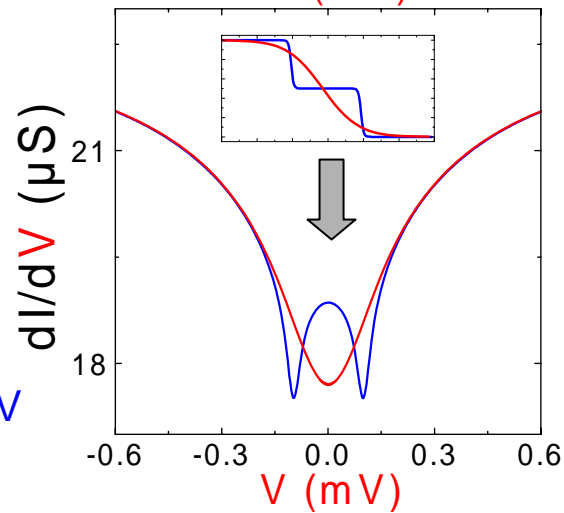
Measure $f(E)$ at $B \neq 0$ using Dynamical Coulomb Blockade



$U=0$ mV

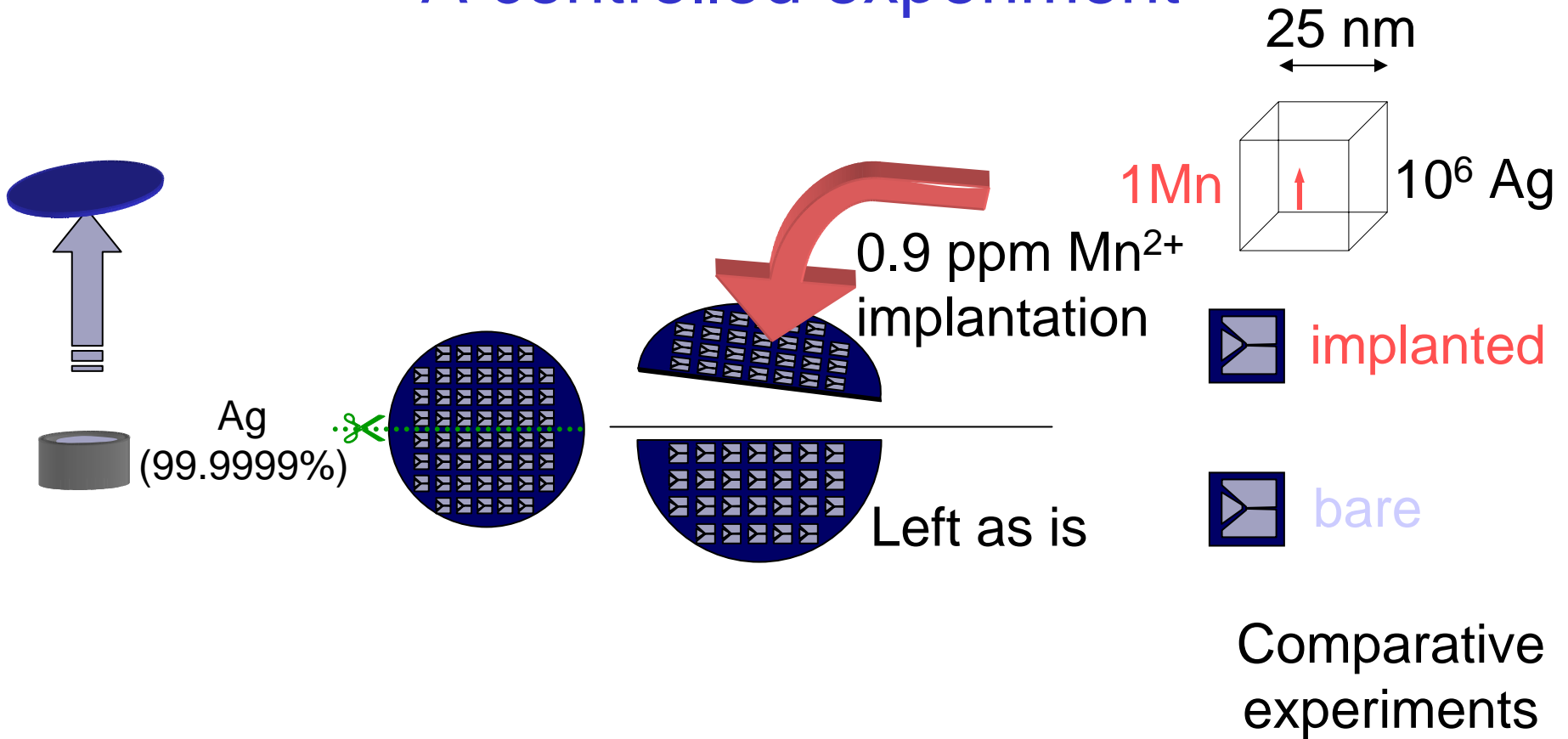


$U=0.2$ mV



$dI/dV \rightarrow f(E) \rightarrow$ electron-electron interactions

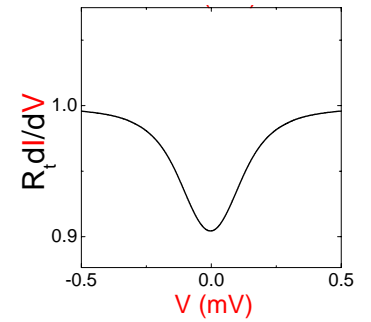
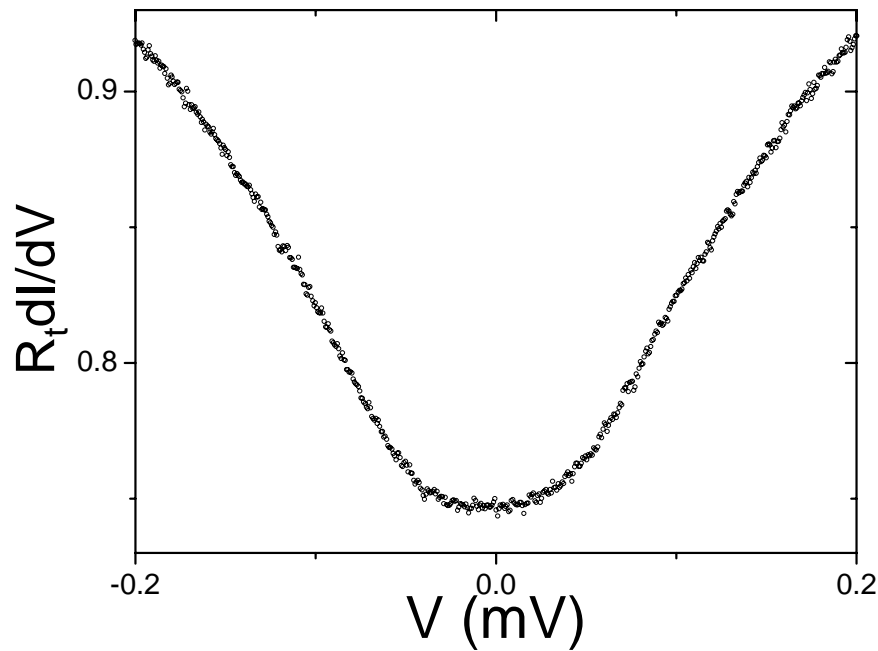
A controlled experiment



Effect of 1 ppm Mn on interactions ?

Experimental data at weak B

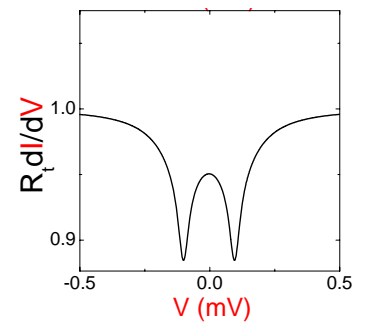
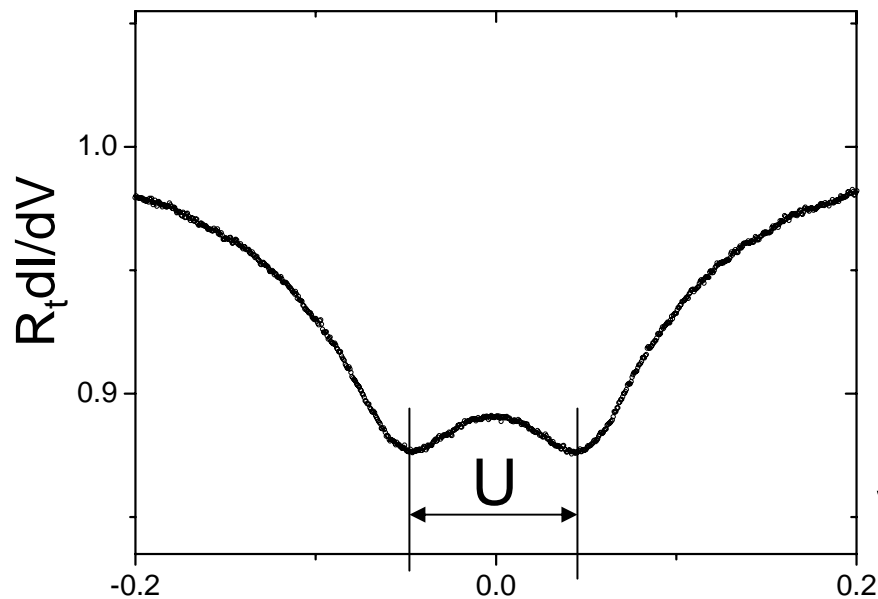
implanted



strong interaction

$U = 0.1$ mV
 $B = 0.3$ T

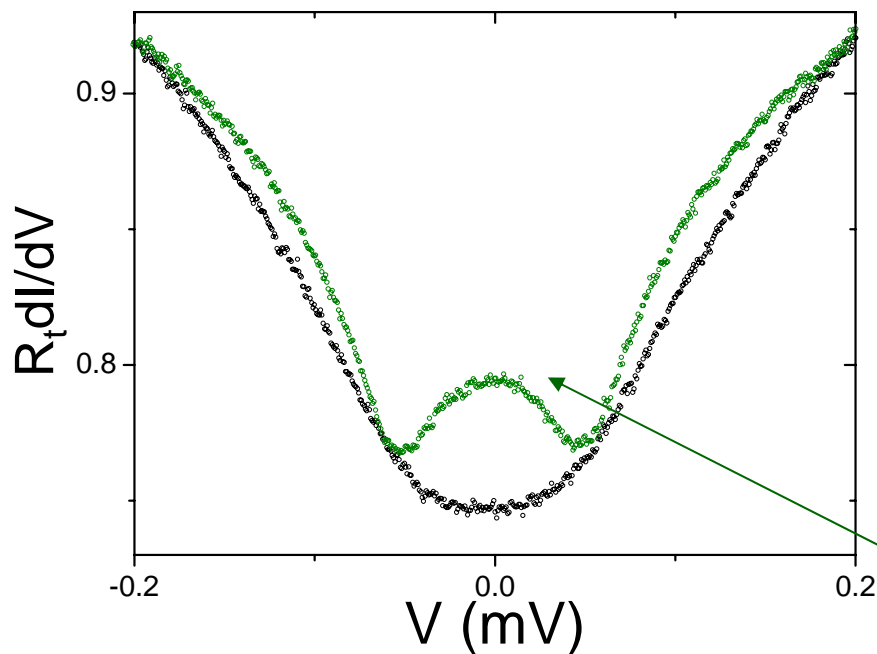
bare



weak interaction

Experimental data at weak and at strong B

implanted



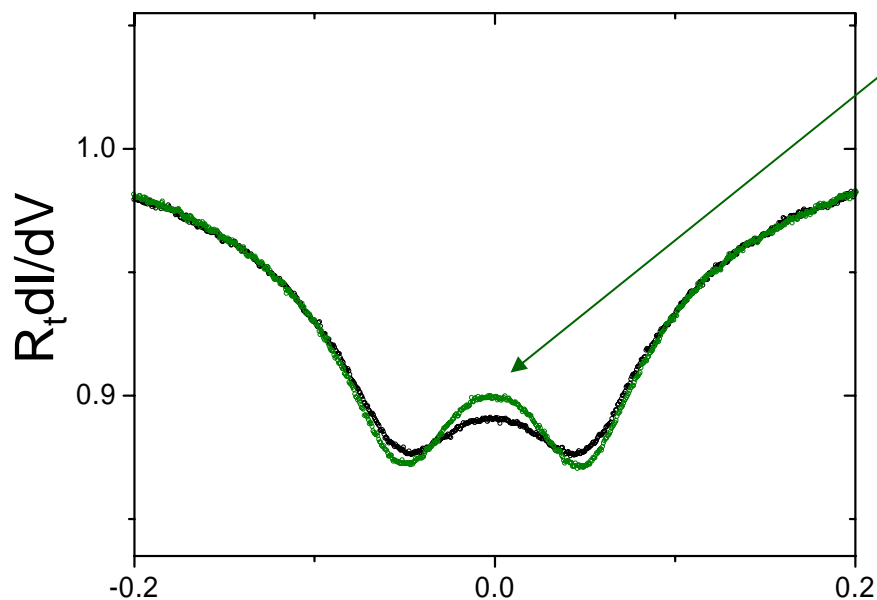
$U = 0.1$ mV

$B = 0.3$ T

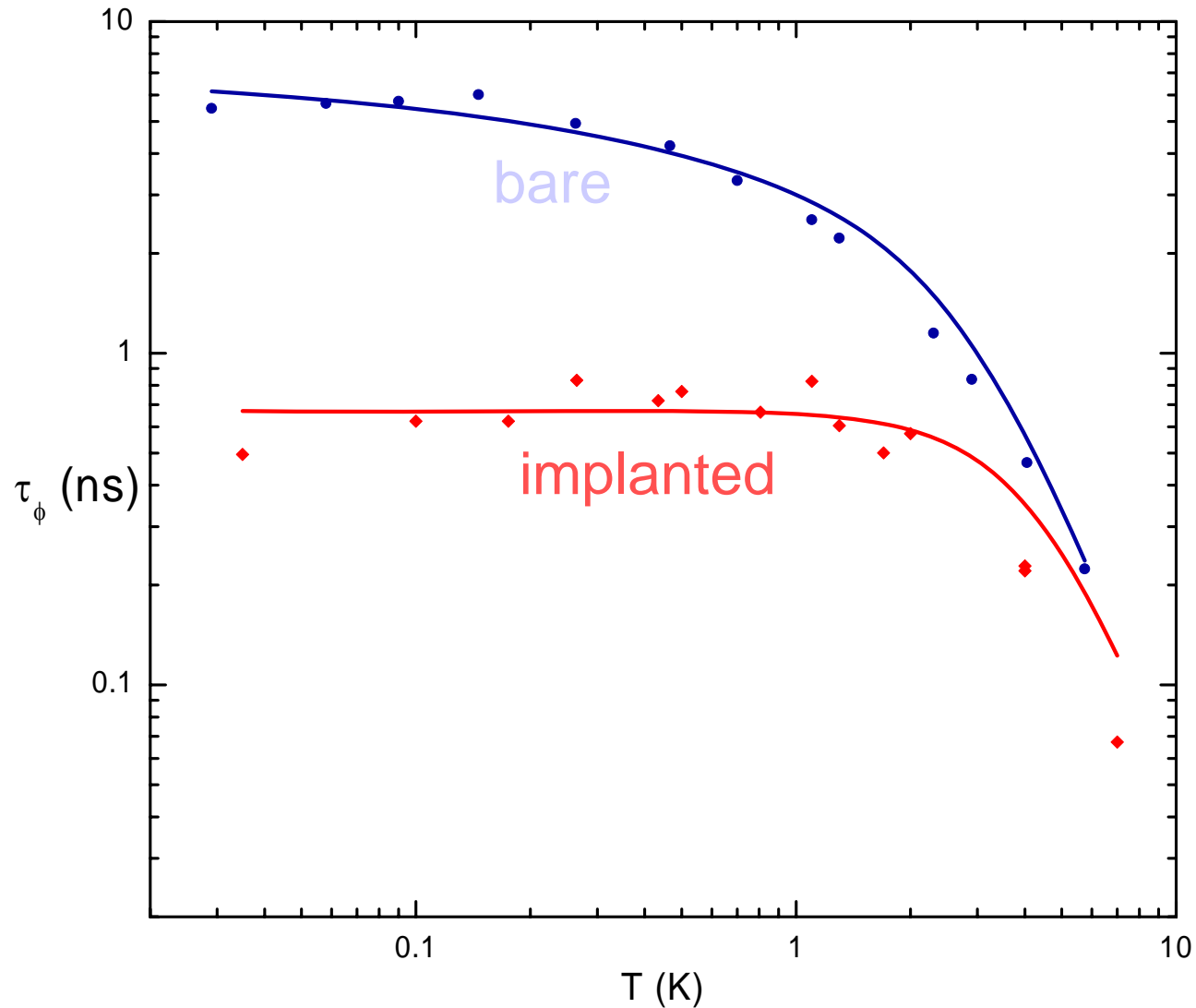
$B = 2.1$ T

Very weak
interaction

bare



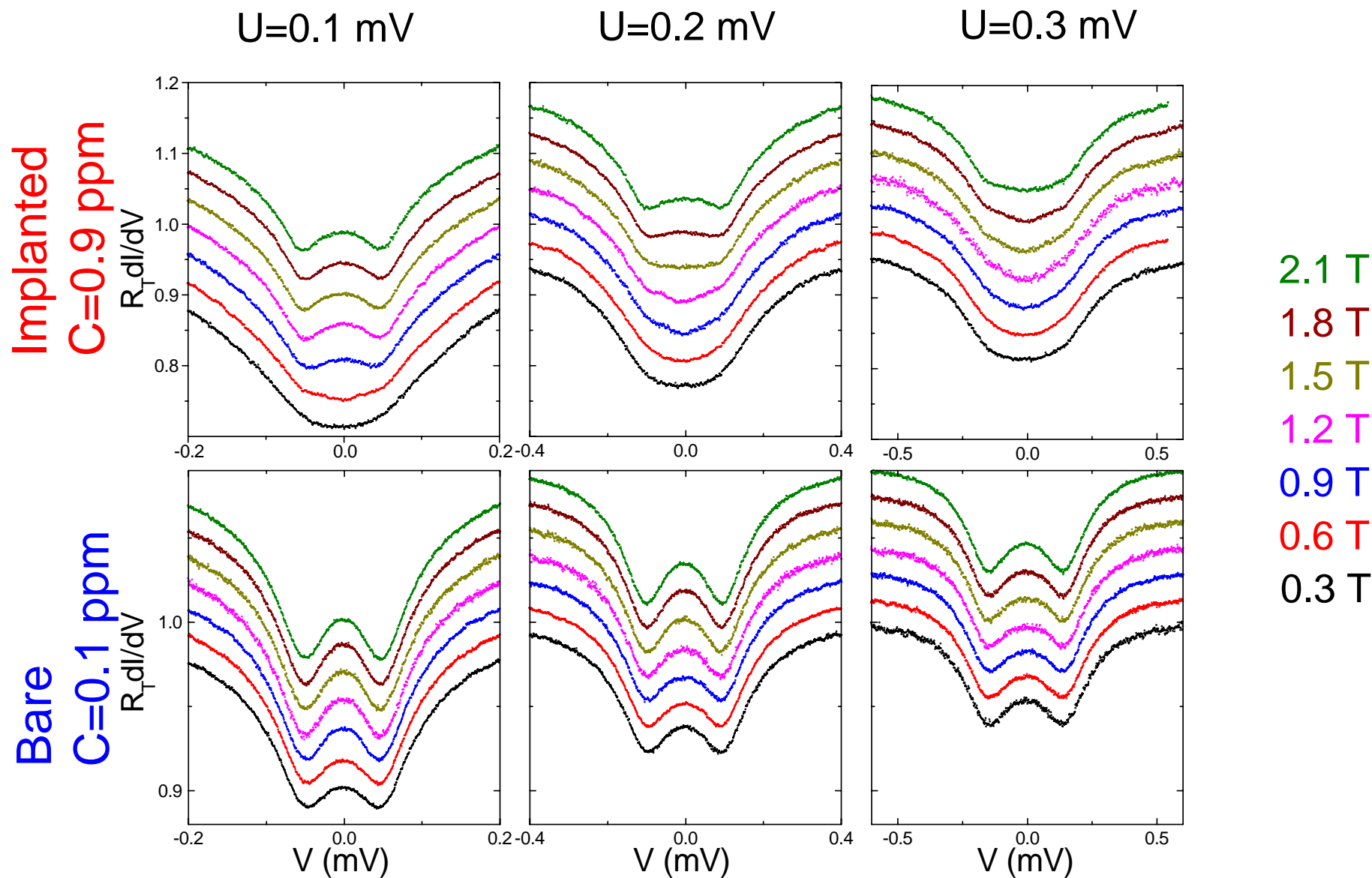
Coherence time measurements on the same 2 samples



Fits:

$$C_{\text{bare}} = 0.1 \text{ ppm}$$
$$C_{\text{implanted}} = 0.9 \text{ ppm}$$

Full U, B dependence



Comparison with theory $\left(s = \frac{1}{2}\right)$

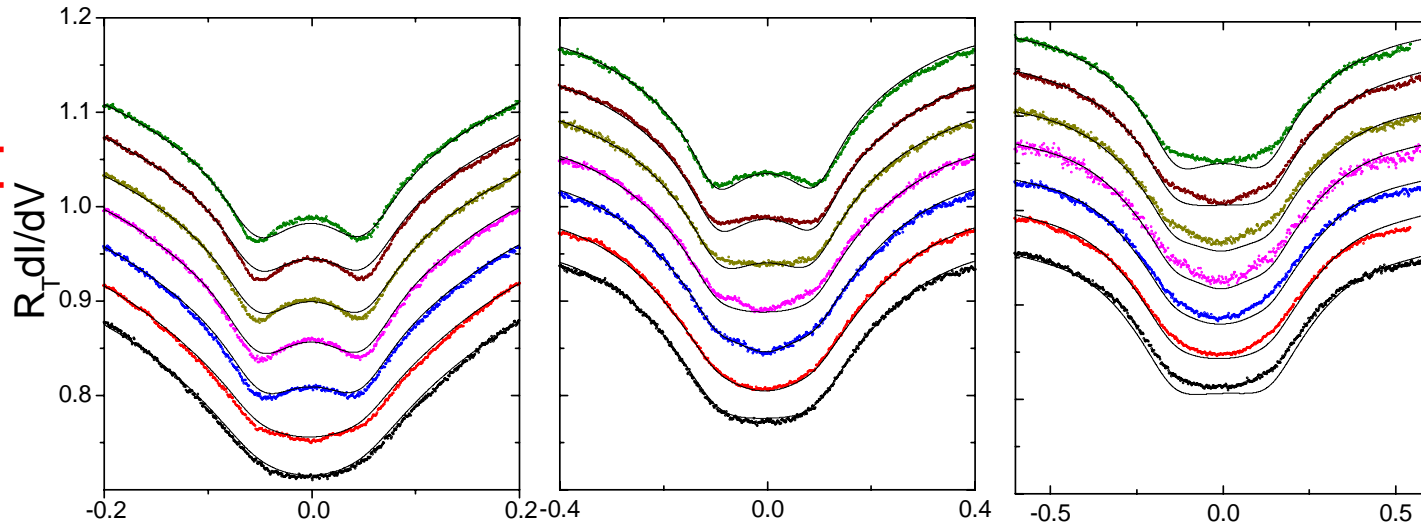
Goeppert, Galperin, Altshuler and Grabert, PRB 64, 033301 (2001)

$U=0.1$ mV

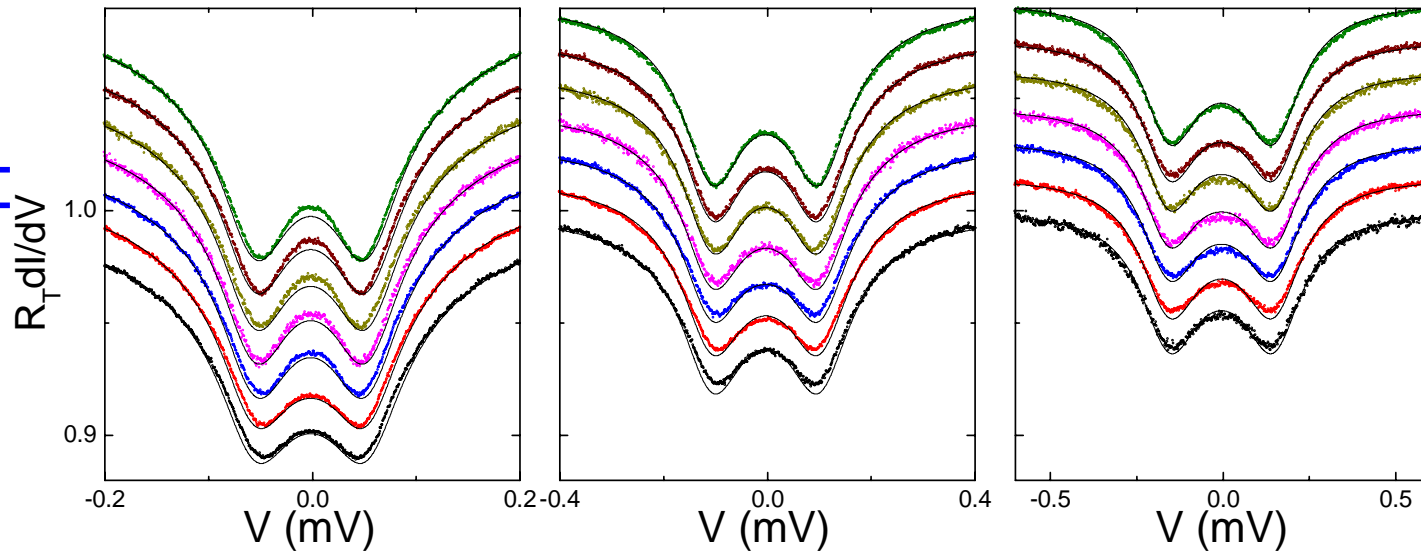
$U=0.2$ mV

$U=0.3$ mV

Implanted
 $C=0.9$ ppm



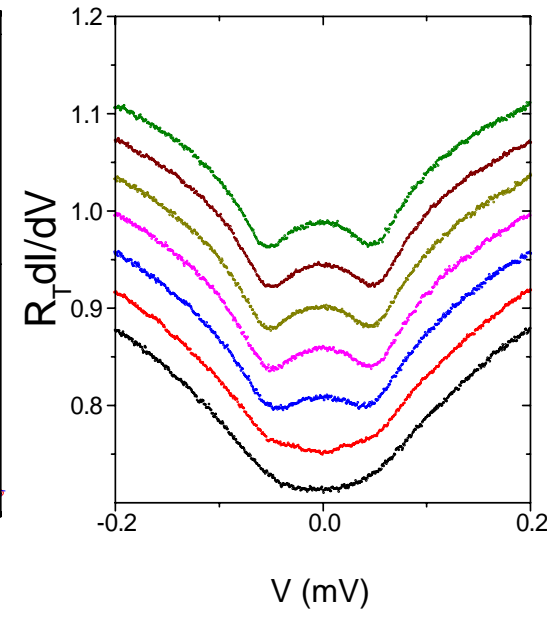
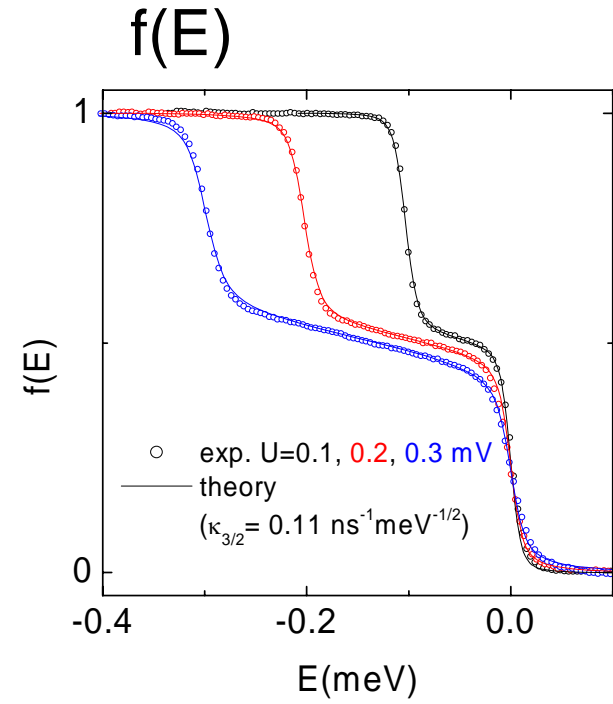
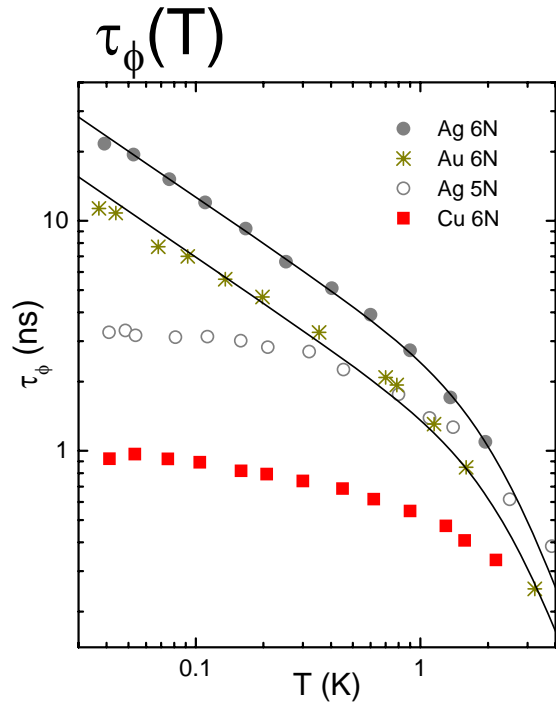
Bare
 $C=0.1$ ppm



2.1 T
1.8 T
1.5 T
1.2 T
0.9 T
0.6 T
0.3 T

Conclusions – Lectures 2 & 3

Two methods to investigate interactions in wires

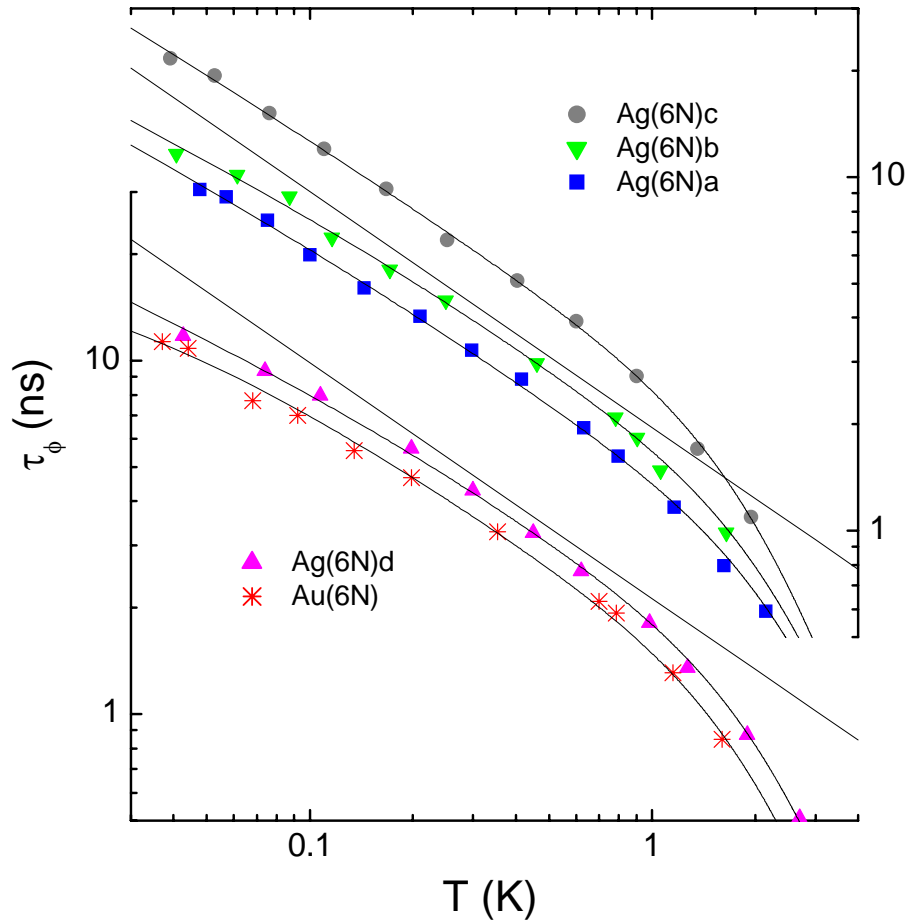


Moral of the story: even at concentrations as low as **1 ppm**, magnetic impurities have a large influence on low-temperature electronic transport in metals.

References

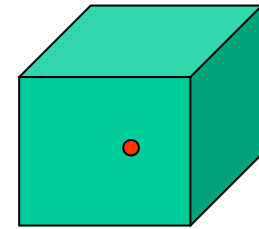
- Dephasing
 - Gougam, Pierre, Pothier, Esteve, Birge, J. Low Temp. Phys. **118**, 447 (2000).
 - Pierre & Birge, Phys. Rev. Lett. **89**, 206804 (2002).
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 - Anthore, Pierre, Pothier, Esteve, Devoret, cond-mat/0109297 (2001).
 - Anthore, Pierre, Pothier, Esteve, Phys. Rev. Lett. **90**, 076806 (2003).
- Both
 - Pierre, Pothier, Esteve, Devoret, Gougam, Birge, cond-mat/0012038 (2000).
 - Pierre, Ann. Phys. Fr. **26**, N°4 (2001).
 - Huard, Anthore, Birge, Pothier, Esteve, to be published in PRL (2005).

Evidence for extremely dilute magnetic impurities even in purest samples



Sample	Imp.	T_K (K)	c (ppm)
Ag(6N)a	Mn	0.04	0.009
" b	"	"	0.011
" c	"	"	0.0024
" d	"	"	0.012
Au(6N)	Cr	0.01	0.02

1 ppm :



100 atoms ~ 25 nm

In the wire, 0.01 ppm = 3 impurities/ μ m

Compare τ_ϕ data with AAK and GZS theories

